

# ISO7840x High-Performance, 8000V<sub>PK</sub> Reinforced Quad-Channel Digital Isolator

## 1 Features

- Signaling Rate: Up to 100Mbps
- Wide Supply Range: 2.25V to 5.5V
- 2.25V to 5.5V Level Translation
- Wide Temperature Range: –55°C to 125°C
- Low-Power Consumption, Typical 1.7mA per Channel at 1Mbps
- Low Propagation Delay: 11ns Typical (5V Supplies)
- Industry leading CMTI (Min): ±100kV/μs
- Robust Electromagnetic Compatibility (EMC)
- System-Level ESD, EFT, and Surge Immunity
- Low Emissions
- Isolation Barrier Life: >40 Years
- Wide Body SOIC-16 Package and Extra-Wide Body SOIC-16 Package Options
- Safety and Regulatory Approvals:
  - 8000V<sub>PK</sub> Reinforced Isolation per DIN EN IEC 60747-17 (VDE 0884-17)
  - 5.7kV<sub>RMS</sub> Isolation for 1 Minute per UL 1577
  - IEC 61010-1, IEC 62368-1, IEC 60601-1, and GB 4943.1 certifications

## 2 Applications

- [Industrial Automation](#)
- [Motor Control](#)
- [Power Supplies](#)
- [Solar Inverters](#)
- [Medical Equipment](#)
- [Hybrid Electric Vehicles](#)

## 3 Description

The ISO7840x device is a high-performance, quad-channel digital isolator with a 8000V<sub>PK</sub> isolation voltage. This device has reinforced isolation certifications according to VDE, CSA, CQC, and TUV. The isolator provides high electromagnetic immunity and low emissions at low-power consumption while isolating CMOS or LVC MOS digital I/Os. Each isolation channel has a logic input and output buffer separated by a silicon-dioxide (SiO<sub>2</sub>) insulation barrier.

This device comes with enable pins that can be used to put the respective outputs in high impedance for multi-controller driving applications and to reduce power consumption. The ISO7840 device has four forward and zero reverse-direction channels. If the input power or signal is lost, the default output is *high* for the ISO7840 device and *low* for the ISO7840F

device. See the [Device Functional Modes](#) section for further details.

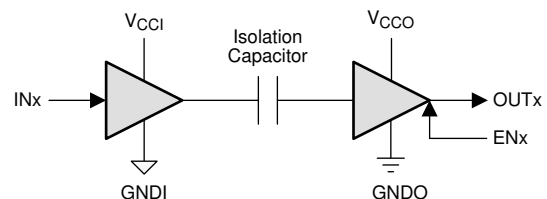
Used in conjunction with isolated power supplies, this device helps prevent noise currents on a data bus or other circuits from entering the local ground and interfering with or damaging sensitive circuitry. Through remarkable chip design and layout techniques, electromagnetic compatibility of the ISO7840 device has been significantly enhanced to ease system-level ESD, EFT, surge, and emissions compliance.

The ISO7840 device is available in 16-pin SOIC wide-body (DW) and extra-wide body (DWW) packages.

### Package Information

| PART NUMBER         | PACKAGE <sup>(1)</sup> | PACKAGE SIZE <sup>(2)</sup> | BODY SIZE (NOM)  |
|---------------------|------------------------|-----------------------------|------------------|
| ISO7840<br>ISO7840F | DW (16, SOIC)          | 10.30mm × 10.30mm           | 10.30mm × 7.50mm |
|                     | DWW (16, SOIC)         | 10.30mm × 17.25mm           | 10.30mm × 14.0mm |

- (1) For all available packages, see the orderable addendum at the end of the data sheet.
- (2) The package size (length × width) is a nominal value and includes pins, where applicable.



V<sub>CCI</sub> and GNDI are supply and ground connections respectively for the input channels.

V<sub>CCO</sub> and GNDO are supply and ground connections respectively for the output channels.

### Simplified Schematic



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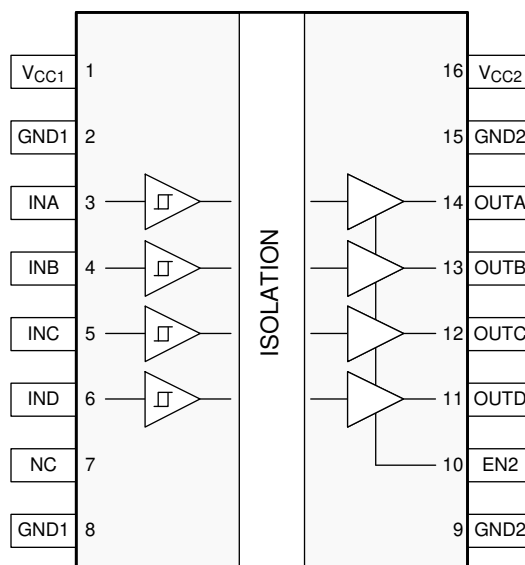
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## 4 Pin Configuration and Functions

### Pin Functions

| PIN              |     | Type <sup>(1)</sup> | DESCRIPTION                                                                                                              |
|------------------|-----|---------------------|--------------------------------------------------------------------------------------------------------------------------|
| NAME             | NO. |                     |                                                                                                                          |
| EN2              | 10  | I                   | Output enable 2. Output pins on side 2 are enabled when EN2 is high or open and in high-impedance state when EN2 is low. |
| GND1             | 2   | —                   | Ground connection for V <sub>CC1</sub>                                                                                   |
|                  | 8   |                     |                                                                                                                          |
| GND2             | 9   | —                   | Ground connection for V <sub>CC2</sub>                                                                                   |
|                  | 15  |                     |                                                                                                                          |
| INA              | 3   | I                   | Input, channel A                                                                                                         |
| INB              | 4   | I                   | Input, channel B                                                                                                         |
| INC              | 5   | I                   | Input, channel C                                                                                                         |
| IND              | 6   | I                   | Input, channel D                                                                                                         |
| NC               | 7   | —                   | Not connected                                                                                                            |
| OUTA             | 14  | O                   | Output, channel A                                                                                                        |
| OUTB             | 13  | O                   | Output, channel B                                                                                                        |
| OUTC             | 12  | O                   | Output, channel C                                                                                                        |
| OUTD             | 11  | O                   | Output, channel D                                                                                                        |
| V <sub>CC1</sub> | 1   | —                   | Power supply, V <sub>CC1</sub>                                                                                           |
| V <sub>CC2</sub> | 16  | —                   | Power supply, V <sub>CC2</sub>                                                                                           |

(1) I = Input, O = Output



**Figure 4-1. DW and DWW Packages 16-Pin SOIC Top View**

## 5 Specifications

### 5.1 Absolute Maximum Ratings

See (1)

|                          |                               | MIN  | MAX                   | UNIT |
|--------------------------|-------------------------------|------|-----------------------|------|
| $V_{CC1}$ ,<br>$V_{CC2}$ | Supply voltage <sup>(2)</sup> | -0.5 | 6                     | V    |
| Voltage                  | INx                           | -0.5 | $V_{CCX} + 0.5^{(3)}$ | V    |
|                          | OUTx                          | -0.5 | $V_{CCX} + 0.5^{(3)}$ |      |
|                          | EN2                           | -0.5 | $V_{CCX} + 0.5^{(3)}$ |      |
| $I_O$                    | Output current                | -15  | 15                    | mA   |
|                          | Surge immunity                |      | 12.8                  | kV   |
| $T_{stg}$                | Storage temperature           | -65  | 150                   | °C   |

- (1) Operation outside the *Absolute Maximum Ratings* may cause permanent device damage. *Absolute Maximum Ratings* do not imply functional operation of the device at these or any other conditions beyond those listed under *Recommended Operating Conditions*. If used outside the *Recommended Operating Conditions* but within the *Absolute Maximum Ratings*, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.
- (2) All voltage values except differential I/O bus voltages are with respect to the local ground terminal (GND1 or GND2) and are peak voltage values.
- (3) Maximum voltage must not exceed 6V

### 5.2 ESD Ratings

|                    |                         |                                                                                          | VALUE | UNIT |
|--------------------|-------------------------|------------------------------------------------------------------------------------------|-------|------|
| V <sub>(ESD)</sub> | Electrostatic discharge | Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins <sup>(1)</sup>              | ±6000 | V    |
|                    |                         | Charged device model (CDM), per JEDEC specification JESD22-C101, all pins <sup>(2)</sup> | ±1500 |      |

- (1) JEDEC document JEP155 states that 500V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250V CDM allows safe manufacturing with a standard ESD control process.

### 5.3 Recommended Operating Conditions

|                       |                                     | MIN                        | NOM | MAX                        | UNIT |
|-----------------------|-------------------------------------|----------------------------|-----|----------------------------|------|
| $V_{CC1}$ , $V_{CC2}$ | Supply voltage                      | 2.25                       |     | 5.5                        | V    |
| $I_{OH}$              | High-level output current           | $V_{CCO}^{(2)} = 5V$       | -4  |                            | mA   |
|                       |                                     | $V_{CCO}^{(2)} = 3.3V$     | -2  |                            |      |
|                       |                                     | $V_{CCO}^{(2)} = 2.5V$     | -1  |                            |      |
| $I_{OL}$              | Low-level output current            | $V_{CCO}^{(2)} = 5V$       | 4   |                            | mA   |
|                       |                                     | $V_{CCO}^{(2)} = 3.3V$     | 2   |                            |      |
|                       |                                     | $V_{CCO}^{(2)} = 2.5V$     | 1   |                            |      |
| $V_{IH}$              | High-level input voltage            | $0.7 \times V_{CCI}^{(2)}$ |     | $V_{CCI}^{(2)}$            | V    |
| $V_{IL}$              | Low-level input voltage             | 0                          |     | $0.3 \times V_{CCI}^{(2)}$ | V    |
| DR                    | Signaling Rate                      | 0                          |     | 100                        | Mbps |
| $T_J$                 | Junction temperature <sup>(1)</sup> | -55                        |     | 150                        | °C   |
| $T_A$                 | Ambient temperature                 | -55                        | 25  | 125                        | °C   |

- (1) To maintain the recommended operating conditions for  $T_J$ , see [Section 5.4](#).
- (2)  $V_{CCI}$  = Input-side  $V_{CC}$ ;  $V_{CCO}$  = Output-side  $V_{CC}$ .

## 5.4 Thermal Information

| THERMAL METRIC <sup>(1)</sup> |                                              | ISO7840   |            | UNIT |
|-------------------------------|----------------------------------------------|-----------|------------|------|
|                               |                                              | DW (SOIC) | DWW (SOIC) |      |
|                               |                                              | 16 Pins   | 16 Pins    |      |
| R <sub>θJA</sub>              | Junction-to-ambient thermal resistance       | 78.9      | 78.9       | °C/W |
| R <sub>θJC(top)</sub>         | Junction-to-case(top) thermal resistance     | 41.6      | 41.1       | °C/W |
| R <sub>θJB</sub>              | Junction-to-board thermal resistance         | 43.6      | 49.5       | °C/W |
| Ψ <sub>JT</sub>               | Junction-to-top characterization parameter   | 15.5      | 15.2       | °C/W |
| Ψ <sub>JB</sub>               | Junction-to-board characterization parameter | 43.1      | 48.8       | °C/W |
| R <sub>θJC(bottom)</sub>      | Junction-to-case(bottom) thermal resistance  | N/A       | N/A        | °C/W |

(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application note.

## 5.5 Power Ratings

V<sub>CC1</sub> = V<sub>CC2</sub> = 5.5V, T<sub>J</sub> = 150°C, C<sub>L</sub> = 15pF, input a 50MHz 50% duty cycle square wave

| PARAMETER       |                                                 | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|-----------------|-------------------------------------------------|-----------------|-----|-----|-----|------|
| P <sub>D</sub>  | Maximum power dissipation by ISO7840x           |                 |     |     | 200 | mW   |
| P <sub>D1</sub> | Maximum power dissipation by side-1 of ISO7840x |                 |     |     | 40  | mW   |
| P <sub>D2</sub> | Maximum power dissipation by side-2 of ISO7840x |                 |     |     | 160 | mW   |

## 5.6 Insulation Specifications

| PARAMETER                                        |                                                      | TEST CONDITIONS                                                                                                                                                                                                                                                                                     | SPECIFICATION     |                   | UNIT             |
|--------------------------------------------------|------------------------------------------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-------------------|-------------------|------------------|
|                                                  |                                                      |                                                                                                                                                                                                                                                                                                     | DW                | DWW               |                  |
| GENERAL                                          |                                                      |                                                                                                                                                                                                                                                                                                     |                   |                   |                  |
| CLR                                              | External clearance <sup>(1)</sup>                    | Shortest pin-to-pin distance through air                                                                                                                                                                                                                                                            | >8.15             | >14.5             | mm               |
|                                                  |                                                      | Shortest pin-to-pin distance through air (typical)                                                                                                                                                                                                                                                  |                   | 15.0              | mm               |
| CPG                                              | External creepage <sup>(1)</sup>                     | Shortest pin-to-pin distance across the package surface                                                                                                                                                                                                                                             | >8.15             | >14.5             | mm               |
|                                                  |                                                      | Shortest pin-to-pin distance across the package surface (typical)                                                                                                                                                                                                                                   |                   | 15.0              | mm               |
| DTI                                              | Distance through the insulation                      | Minimum internal gap (internal clearance)                                                                                                                                                                                                                                                           | >21               | >21               | μm               |
| CTI                                              | Comparative tracking index                           | DIN EN 60112 (VDE 0303-11); IEC 60112; UL 746A                                                                                                                                                                                                                                                      | >600              | >600              | V                |
|                                                  | Material group                                       |                                                                                                                                                                                                                                                                                                     | I                 | I                 |                  |
|                                                  | Overvoltage category per IEC 60664-1                 | Rated mains voltage ≤ 600V <sub>RMS</sub>                                                                                                                                                                                                                                                           | I–IV              | I–IV              |                  |
|                                                  |                                                      | Rated mains voltage ≤ 1000V <sub>RMS</sub>                                                                                                                                                                                                                                                          | I–III             | I–IV              |                  |
| DIN EN IEC 60747-17 (VDE 0884-17) <sup>(2)</sup> |                                                      |                                                                                                                                                                                                                                                                                                     |                   |                   |                  |
| V <sub>IORM</sub>                                | Maximum repetitive peak isolation voltage            |                                                                                                                                                                                                                                                                                                     | 2121              | 2828              | V <sub>PK</sub>  |
| V <sub>IOWM</sub>                                | Maximum isolation working voltage                    | AC voltage (sine wave); Time dependent dielectric breakdown (TDDb) Test, see <a href="#">Figure 5-1</a> and <a href="#">Figure 5-2</a>                                                                                                                                                              | 1500              | 2000              | V <sub>RMS</sub> |
|                                                  |                                                      | DC voltage                                                                                                                                                                                                                                                                                          | 2121              | 2828              | V <sub>DC</sub>  |
| V <sub>IOTM</sub>                                | Maximum transient isolation voltage                  | V <sub>TEST</sub> = V <sub>IOTM</sub> , t = 60s (qualification)<br>V <sub>TEST</sub> = 1.2 x V <sub>IOTM</sub> , t= 1s (100% production)                                                                                                                                                            | 8000              | 8000              | V <sub>PK</sub>  |
| V <sub>IMP</sub>                                 | Maximum impulse voltage <sup>(3)</sup>               | Tested in air, 1.2/50μs waveform per IEC 62368-1                                                                                                                                                                                                                                                    | 9800              | 9800              | V <sub>PK</sub>  |
| V <sub>IOSM</sub>                                | Maximum surge isolation voltage <sup>(4)</sup>       | V <sub>IOSM</sub> ≥ 1.3 x V <sub>IMP</sub> ; Tested in oil (qualification test), 1.2/50-μs waveform per IEC 62368-1                                                                                                                                                                                 | 12800             | 12800             | V <sub>PK</sub>  |
| q <sub>pd</sub>                                  | Apparent charge <sup>(5)</sup>                       | Method a: After I/O safety test subgroup 2/3,<br>V <sub>ini</sub> = V <sub>IOTM</sub> , t <sub>ini</sub> = 60s;<br>V <sub>pd(m)</sub> = 1.2 x V <sub>IOTM</sub> = 2545V <sub>PK</sub> (DW) and 3394V <sub>PK</sub> (DWW), t <sub>m</sub> = 10s                                                      | ≤5                | ≤5                | pC               |
|                                                  |                                                      | Method a: After environmental tests subgroup 1,<br>V <sub>ini</sub> = V <sub>IOTM</sub> , t <sub>ini</sub> = 60s;<br>V <sub>pd(m)</sub> = 1.6 x V <sub>IORM</sub> = 3394V <sub>PK</sub> (DW) and 4525V <sub>PK</sub> (DWW), t <sub>m</sub> = 10s                                                    | ≤5                | ≤5                |                  |
|                                                  |                                                      | Method b: At routine test (100% production);<br>V <sub>ini</sub> = 1.2 x V <sub>IOTM</sub> , t <sub>ini</sub> = 1s;<br>V <sub>pd(m)</sub> = 1.875 x V <sub>IORM</sub> , t <sub>m</sub> = 1s (method b1) or<br>V <sub>pd(m)</sub> = V <sub>ini</sub> , t <sub>m</sub> = t <sub>ini</sub> (method b2) | ≤5                | ≤5                |                  |
| C <sub>IO</sub>                                  | Barrier capacitance, input to output <sup>(6)</sup>  | V <sub>IO</sub> = 0.4 × sin (2πft), f = 1MHz                                                                                                                                                                                                                                                        | 2                 | 2                 | pF               |
| R <sub>IO</sub>                                  | Isolation resistance, input to output <sup>(6)</sup> | V <sub>IO</sub> = 500V, T <sub>A</sub> = 25°C                                                                                                                                                                                                                                                       | >10 <sup>12</sup> | >10 <sup>12</sup> | Ω                |
|                                                  |                                                      | V <sub>IO</sub> = 500V, 100°C ≤ T <sub>A</sub> ≤ 125°C                                                                                                                                                                                                                                              | >10 <sup>11</sup> | >10 <sup>11</sup> |                  |
|                                                  |                                                      | V <sub>IO</sub> = 500V at T <sub>S</sub> = 150°C                                                                                                                                                                                                                                                    | >10 <sup>9</sup>  | >10 <sup>9</sup>  |                  |
|                                                  | Pollution degree                                     |                                                                                                                                                                                                                                                                                                     | 2                 | 2                 |                  |
|                                                  | Climatic category                                    |                                                                                                                                                                                                                                                                                                     | 55/125/21         | 55/125/21         |                  |
| UL 1577                                          |                                                      |                                                                                                                                                                                                                                                                                                     |                   |                   |                  |
| V <sub>ISO</sub>                                 | Withstand isolation voltage                          | V <sub>TEST</sub> = V <sub>ISO</sub> = 5700V <sub>RMS</sub> , t = 60s (qualification),<br>V <sub>TEST</sub> = 1.2 x V <sub>ISO</sub> = 6840V <sub>RMS</sub> , t = 1s (100% production)                                                                                                              | 5700              | 5700              | V <sub>RMS</sub> |

- (1) Creepage and clearance requirements should be applied according to the specific equipment isolation standards of an application. Care should be taken to maintain the creepage and clearance distance of a board design to ensure that the mounting pads of the isolator on the printed-circuit board do not reduce this distance. Creepage and clearance on a printed-circuit board become equal

in certain cases. Techniques such as inserting grooves, ribs, or both on a printed circuit board are used to help increase these specifications.

- (2) This coupler is suitable for *safe electrical insulation* only within the safety ratings. Compliance with the safety ratings shall be ensured by means of suitable protective circuits.
- (3) Testing is carried out in air to determine the surge immunity of the package.
- (4) Testing is carried out in oil to determine the intrinsic surge immunity of the isolation barrier.
- (5) Apparent charge is electrical discharge caused by a partial discharge (pd).
- (6) All pins on each side of the barrier tied together creating a two-terminal device.

## 5.7 Safety-Related Certifications

| VDE                                                      | CSA                                                | UL                                                           | CQC                                | TUV                                              |
|----------------------------------------------------------|----------------------------------------------------|--------------------------------------------------------------|------------------------------------|--------------------------------------------------|
| Certified according to DIN EN IEC 60747-17 (VDE 0884-17) | Certified according to IEC 62368-1 and IEC 60601-1 | Certified according to UL 1577 Component Recognition Program | Certified according to GB 4943.1   | Certified according to EN 61010-1 and EN 62368-1 |
| Certificate number: 40040142                             | Master contract number: 220991                     | File number: E181974                                         | Certificate number: CQC15001121716 | Client ID number: 77311                          |

## 5.8 Safety Limiting Values

Safety limiting intends to minimize potential damage to the isolation barrier upon failure of input or output circuitry. A failure of the I/O can allow low resistance to ground or the supply and, without current limiting, dissipate sufficient power to overheat the die and damage the isolation barrier potentially leading to secondary system failures.

| PARAMETER      |                                         | TEST CONDITIONS                                                                                    | MIN | TYP | MAX  | UNIT |
|----------------|-----------------------------------------|----------------------------------------------------------------------------------------------------|-----|-----|------|------|
| I <sub>S</sub> | Safety input, output, or supply current | R <sub>θJA</sub> = 78.9°C/W, V <sub>I</sub> = 5.5V, T <sub>J</sub> = 150°C, T <sub>A</sub> = 25°C  |     |     | 288  | mA   |
|                |                                         | R <sub>θJA</sub> = 78.9°C/W, V <sub>I</sub> = 3.6V, T <sub>J</sub> = 150°C, T <sub>A</sub> = 25°C  |     |     | 440  |      |
|                |                                         | R <sub>θJA</sub> = 78.9°C/W, V <sub>I</sub> = 2.75V, T <sub>J</sub> = 150°C, T <sub>A</sub> = 25°C |     |     | 576  |      |
| P <sub>S</sub> | Safety input, output, or total power    | R <sub>θJA</sub> = 78.9°C/W, T <sub>J</sub> = 150°C, T <sub>A</sub> = 25°C                         |     |     | 1584 | mW   |
| T <sub>S</sub> | Maximum safety temperature              |                                                                                                    |     |     | 150  | °C   |

The maximum safety temperature is the maximum junction temperature specified for the device. The power dissipation and junction-to-air thermal impedance of the device installed in the application hardware determines the junction temperature. The assumed junction-to-air thermal resistance in the [Section 5.4](#) is that of a device installed on a high-K test board for leaded surface-mount packages. The power is the recommended maximum input voltage times the current. The junction temperature is then the ambient temperature plus the power times the junction-to-air thermal resistance.

## 5.9 Electrical Characteristics—5V Supply

$V_{CC1} = V_{CC2} = 5V \pm 10\%$  (over recommended operating conditions unless otherwise noted)

| PARAMETER    | TEST CONDITIONS                                                                                                  | MIN                        | TYP                   | MAX | UNIT        |
|--------------|------------------------------------------------------------------------------------------------------------------|----------------------------|-----------------------|-----|-------------|
| $V_{OH}$     | High-level output voltage<br>$I_{OH} = -4mA$ ; see <a href="#">Figure 6-1</a>                                    | $V_{CCO}^{(1)} - 0.4$      | $V_{CCO}^{(1)} - 0.2$ |     | V           |
| $V_{OL}$     | Low-level output voltage<br>$I_{OL} = 4mA$ ; see <a href="#">Figure 6-1</a>                                      |                            | 0.2                   | 0.4 | V           |
| $V_{I(HYS)}$ | Input threshold voltage hysteresis                                                                               | $0.1 \times V_{CCI}^{(1)}$ |                       |     | V           |
| $I_{IH}$     | High-level input current<br>$V_{IH} = V_{CCI}^{(1)}$ at INx or EN2                                               |                            |                       | 10  | $\mu A$     |
| $I_{IL}$     | Low-level input current<br>$V_{IL} = 0V$ at INx or EN2                                                           | -10                        |                       |     | $\mu A$     |
| CMTI         | Common-mode transient immunity<br>$V_I = V_{CCI}^{(1)}$ or 0V, $V_{CM} = 1500V$ ; see <a href="#">Figure 6-4</a> | 100                        |                       |     | kV/ $\mu s$ |
| $C_I$        | Input capacitance<br>$V_I = V_{CC}/2 + 0.4 \times \sin(2\pi ft)$ , $f = 1MHz$ , $V_{CC} = 5V$                    |                            | 2                     |     | pF          |

(1)  $V_{CCI}$  = Input-side  $V_{CC}$ ;  $V_{CCO}$  = Output-side  $V_{CC}$ .

## 5.10 Supply Characteristics—5V Supply

$V_{CC1} = V_{CC2} = 5V \pm 10\%$  (over recommended operating conditions unless otherwise noted)

| PARAMETER      | TEST CONDITIONS                                                   |                                                                           | SUPPLY CURRENT          | MIN | TYP  | MAX  | UNIT |
|----------------|-------------------------------------------------------------------|---------------------------------------------------------------------------|-------------------------|-----|------|------|------|
| Supply current | Disable                                                           | EN2 = 0V, $V_I = 0V$ (ISO7840F), $V_I = V_{CCI}^{(1)}$ (ISO7840)          | $I_{CC1}$               |     | 1.3  | 2    | mA   |
|                |                                                                   |                                                                           | $I_{CC2}$               |     | 0.4  | 0.6  |      |
|                |                                                                   | EN2 = 0V, $V_I = V_{CCI}^{(1)}$ (ISO7840F), $V_I = 0V$ (ISO7840) EN2 = 0V | $I_{CC1}$               |     | 6    | 8.5  | mA   |
|                |                                                                   |                                                                           | $I_{CC2}$               |     | 0.4  | 0.6  |      |
|                | DC signal                                                         | $V_I = 0V$ (ISO7840F), $V_I = V_{CCI}^{(1)}$ (ISO7840)                    | $I_{CC1}$               |     | 1.3  | 2    | mA   |
|                |                                                                   |                                                                           | $I_{CC2}$               |     | 2.2  | 3.1  |      |
|                |                                                                   | $V_I = V_{CCI}^{(1)}$ (ISO7840F), $V_I = 0V$ (ISO7840)                    | $I_{CC1}$               |     | 5.9  | 8.6  | mA   |
|                |                                                                   |                                                                           | $I_{CC2}$               |     | 2.5  | 3.3  |      |
|                | All channels switching with square wave clock input; $C_L = 15pF$ | 1Mbps                                                                     | $I_{CC1}$               |     | 3.6  | 5.3  | mA   |
|                |                                                                   |                                                                           | $I_{CC2}$               |     | 2.6  | 3.7  |      |
|                |                                                                   | 10Mbps                                                                    | $I_{CC1}$               |     | 3.8  | 5.4  | mA   |
|                |                                                                   |                                                                           | $I_{CC2}$               |     | 4.5  | 5.9  |      |
|                |                                                                   | 100Mbps                                                                   | DW package<br>$I_{CC1}$ |     | 5.1  | 5.9  | mA   |
|                |                                                                   |                                                                           | $I_{CC2}$               |     | 23.8 | 27.4 |      |
|                |                                                                   | DWW package                                                               | $I_{CC1}$               |     | 5.1  | 5.9  | mA   |
|                |                                                                   |                                                                           | $I_{CC2}$               |     | 23.8 | 28.5 |      |

(1)  $V_{CCI}$  = Input-side  $V_{CC}$ ;  $V_{CCO}$  = Output-side  $V_{CC}$ .

## 5.11 Electrical Characteristics—3.3V Supply

$V_{CC1} = V_{CC2} = 3.3V \pm 10\%$  (over recommended operating conditions unless otherwise noted)

| PARAMETER    | TEST CONDITIONS                                                                                                  | MIN                        | TYP                   | MAX | UNIT        |
|--------------|------------------------------------------------------------------------------------------------------------------|----------------------------|-----------------------|-----|-------------|
| $V_{OH}$     | High-level output voltage<br>$I_{OH} = -2mA$ ; see <a href="#">Figure 6-1</a>                                    | $V_{CCO}^{(1)} - 0.4$      | $V_{CCO}^{(1)} - 0.2$ |     | V           |
| $V_{OL}$     | Low-level output voltage<br>$I_{OL} = 2mA$ ; see <a href="#">Figure 6-1</a>                                      |                            | 0.2                   | 0.4 | V           |
| $V_{I(HYS)}$ | Input threshold voltage hysteresis                                                                               | $0.1 \times V_{CCI}^{(1)}$ |                       |     | V           |
| $I_{IH}$     | High-level input current<br>$V_{IH} = V_{CCI}^{(1)}$ at INx or EN2                                               |                            |                       | 10  | $\mu A$     |
| $I_{IL}$     | Low-level input current<br>$V_{IL} = 0V$ at INx or EN2                                                           | -10                        |                       |     | $\mu A$     |
| CMTI         | Common-mode transient immunity<br>$V_I = V_{CCI}^{(1)}$ or 0V, $V_{CM} = 1500V$ ; see <a href="#">Figure 6-4</a> | 100                        |                       |     | kV/ $\mu s$ |

(1)  $V_{CCI}$  = Input-side  $V_{CC}$ ;  $V_{CCO}$  = Output-side  $V_{CC}$ .

## 5.12 Supply Current Characteristics—3.3V Supply

$V_{CC1} = V_{CC2} = 3.3V \pm 10\%$  (over recommended operating conditions unless otherwise noted)

| PARAMETER      | TEST CONDITIONS                                                   |                                                                     | SUPPLY CURRENT | MIN | TYP  | MAX  | UNIT |
|----------------|-------------------------------------------------------------------|---------------------------------------------------------------------|----------------|-----|------|------|------|
| Supply current | Disable                                                           | $EN2 = 0V$ , $V_I = 0V$ (ISO7840F), $V_I = V_{CCI}^{(1)}$ (ISO7840) | $I_{CC1}$      |     | 1.3  | 2    | mA   |
|                |                                                                   |                                                                     | $I_{CC2}$      |     | 0.4  | 0.6  |      |
|                |                                                                   | $EN2 = 0V$ , $V_I = V_{CCI}^{(1)}$ (ISO7840F), $V_I = 0V$ (ISO7840) | $I_{CC1}$      |     | 6    | 8.5  | mA   |
|                |                                                                   |                                                                     | $I_{CC2}$      |     | 0.4  | 0.6  |      |
|                | DC signal                                                         | $V_I = 0V$ (ISO7840F), $V_I = V_{CCI}^{(1)}$ (ISO7840)              | $I_{CC1}$      |     | 1.3  | 2    | mA   |
|                |                                                                   |                                                                     | $I_{CC2}$      |     | 2.2  | 3    |      |
|                |                                                                   | $V_I = V_{CCI}^{(1)}$ (ISO7840F), $V_I = 0V$ (ISO7840)              | $I_{CC1}$      |     | 5.9  | 8.6  | mA   |
|                |                                                                   |                                                                     | $I_{CC2}$      |     | 2.4  | 3.3  |      |
|                | All channels switching with square wave clock input; $C_L = 15pF$ | 1Mbps                                                               | $I_{CC1}$      |     | 3.6  | 5.3  | mA   |
|                |                                                                   |                                                                     | $I_{CC2}$      |     | 2.5  | 3.6  |      |
|                |                                                                   | 10Mbps                                                              | $I_{CC1}$      |     | 3.7  | 5.3  | mA   |
|                |                                                                   |                                                                     | $I_{CC2}$      |     | 3.9  | 5.1  |      |
|                |                                                                   | 100Mbps                                                             | $I_{CC1}$      |     | 4.5  | 5.8  | mA   |
|                |                                                                   |                                                                     | $I_{CC2}$      |     | 17.7 | 20.6 |      |

(1)  $V_{CCI}$  = Input-side  $V_{CC}$ ;  $V_{CCO}$  = Output-side  $V_{CC}$ .

### 5.13 Electrical Characteristics—2.5V Supply

$V_{CC1} = V_{CC2} = 2.5V \pm 10\%$  (over recommended operating conditions unless otherwise noted)

| PARAMETER                                       | TEST CONDITIONS                                                                | MIN                        | TYP                   | MAX | UNIT        |
|-------------------------------------------------|--------------------------------------------------------------------------------|----------------------------|-----------------------|-----|-------------|
| $V_{OH}$ High-level output voltage              | $I_{OH} = -1mA$ ; see <a href="#">Figure 6-1</a>                               | $V_{CCO}^{(1)} - 0.4$      | $V_{CCO}^{(1)} - 0.2$ |     | V           |
| $V_{OL}$ Low-level output voltage               | $I_{OL} = 1mA$ ; see <a href="#">Figure 6-1</a>                                |                            | 0.2                   | 0.4 | V           |
| $V_{I(HYS)}$ Input threshold voltage hysteresis |                                                                                | $0.1 \times V_{CCI}^{(1)}$ |                       |     | V           |
| $I_{IH}$ High-level input current               | $V_{IH} = V_{CCI}^{(1)}$ at INx or EN2                                         |                            |                       | 10  | $\mu A$     |
| $I_{IL}$ Low-level input current                | $V_{IL} = 0V$ at INx or EN2                                                    | -10                        |                       |     | $\mu A$     |
| CMTI Common-mode transient immunity             | $V_I = V_{CCI}^{(1)}$ or 0V, $V_{CM} = 1500V$ ; see <a href="#">Figure 6-4</a> | 100                        |                       |     | kV/ $\mu s$ |

(1)  $V_{CCI}$  = Input-side  $V_{CC}$ ;  $V_{CCO}$  = Output-side  $V_{CC}$ .

### 5.14 Supply Current Characteristics—2.5V Supply

$V_{CC1} = V_{CC2} = 2.5V \pm 10\%$  (over recommended operating conditions unless otherwise noted)

| PARAMETER      | TEST CONDITIONS                                                   |                                                                                                | SUPPLY CURRENT | MIN | TYP  | MAX  | UNIT |
|----------------|-------------------------------------------------------------------|------------------------------------------------------------------------------------------------|----------------|-----|------|------|------|
| Supply current | Disable                                                           | EN2 = 0V, $V_I = 0V$ (Devices with suffix F), $V_I = V_{CCI}^{(1)}$ (Devices without suffix F) | $I_{CC1}$      |     | 1.3  | 2    | mA   |
|                |                                                                   |                                                                                                | $I_{CC2}$      |     | 0.4  | 0.6  |      |
|                |                                                                   | EN2 = 0V, $V_I = V_{CCI}^{(1)}$ (Devices with suffix F), $V_I = 0V$ (Devices without suffix F) | $I_{CC1}$      |     | 6    | 8.5  | mA   |
|                |                                                                   |                                                                                                | $I_{CC2}$      |     | 0.4  | 0.6  |      |
|                | DC signal                                                         | $V_I = 0V$ (Devices with suffix F), $V_I = V_{CCI}^{(1)}$ (Devices without suffix F)           | $I_{CC1}$      |     | 1.3  | 2    | mA   |
|                |                                                                   |                                                                                                | $I_{CC2}$      |     | 2.2  | 3    |      |
|                |                                                                   | $V_I = V_{CCI}^{(1)}$ (Devices with suffix F), $V_I = 0V$ (Devices without suffix F)           | $I_{CC1}$      |     | 5.9  | 8.6  | mA   |
|                |                                                                   |                                                                                                | $I_{CC2}$      |     | 2.4  | 3.3  |      |
|                | All channels switching with square wave clock input; $C_L = 15pF$ | 1Mbps                                                                                          | $I_{CC1}$      |     | 3.6  | 5.3  | mA   |
|                |                                                                   |                                                                                                | $I_{CC2}$      |     | 2.5  | 3.5  |      |
|                |                                                                   | 10Mbps                                                                                         | $I_{CC1}$      |     | 3.7  | 5.3  | mA   |
|                |                                                                   |                                                                                                | $I_{CC2}$      |     | 3.5  | 4.7  |      |
|                |                                                                   | 100Mbps                                                                                        | $I_{CC1}$      |     | 4.4  | 5.7  | mA   |
|                |                                                                   |                                                                                                | $I_{CC2}$      |     | 13.9 | 16.4 |      |

(1)  $V_{CCI}$  = Input-side  $V_{CC}$ ;  $V_{CCO}$  = Output-side  $V_{CC}$ .

## 5.15 Switching Characteristics—5V Supply

$V_{CC1} = V_{CC2} = 5V \pm 10\%$  (over recommended operating conditions unless otherwise noted)

| PARAMETER                           |                                                                            | TEST CONDITIONS                                                        | MIN  | TYP  | MAX | UNIT |
|-------------------------------------|----------------------------------------------------------------------------|------------------------------------------------------------------------|------|------|-----|------|
| t <sub>PLH</sub> , t <sub>PHL</sub> | Propagation delay time                                                     | See Figure 6-1                                                         | 6    | 11   | 16  | ns   |
| PWD                                 | Pulse width distortion <sup>(1)</sup>  t <sub>PHL</sub> – t <sub>PLH</sub> |                                                                        | 0.55 | 4.1  | ns  |      |
| t <sub>sk(o)</sub>                  | Channel-to-channel output skew time <sup>(2)</sup>                         | Same-direction channels                                                |      |      | 2.5 | ns   |
| t <sub>sk(pp)</sub>                 | Part-to-part skew time <sup>(3)</sup>                                      |                                                                        |      |      | 4.5 | ns   |
| t <sub>r</sub>                      | Output signal rise time                                                    | See Figure 6-1                                                         |      | 1.7  | 3.9 | ns   |
| t <sub>f</sub>                      | Output signal fall time                                                    |                                                                        |      | 1.9  | 3.9 | ns   |
| t <sub>PHZ</sub>                    | Disable propagation delay, high-to-high impedance output                   | See Figure 6-2                                                         |      | 12   | 20  | ns   |
| t <sub>PLZ</sub>                    | Disable propagation delay, low-to-high impedance output                    |                                                                        |      | 12   | 20  | ns   |
| t <sub>PZH</sub>                    | Enable propagation delay, high impedance-to-high output for ISO7840        |                                                                        |      | 10   | 20  | ns   |
|                                     | Enable propagation delay, high impedance-to-high output for ISO7840F       |                                                                        |      | 2    | 2.5 | μs   |
| t <sub>PZL</sub>                    | Enable propagation delay, high impedance-to-low output for ISO7840         |                                                                        |      | 2    | 2.5 | μs   |
|                                     | Enable propagation delay, high impedance-to-low output for ISO7840F        |                                                                        |      | 10   | 20  | ns   |
| t <sub>fs</sub>                     | Default output delay time from input power loss                            | Measured from the time V <sub>CC</sub> goes below 1.7V. See Figure 6-3 |      | 0.2  | 9   | μs   |
| t <sub>ie</sub>                     | Time interval error                                                        | 2 <sup>16</sup> – 1 PRBS data at 100Mbps                               |      | 0.90 |     | ns   |

- (1) Also known as pulse skew.
- (2)  $t_{sk(o)}$  is the skew between outputs of a single device with all driving inputs connected together and the outputs switching in the same direction while driving identical loads.
- (3)  $t_{sk(pp)}$  is the magnitude of the difference in propagation delay times between any terminals of different devices switching in the same direction while operating at identical supply voltages, temperature, input signals and loads.

## 5.16 Switching Characteristics—3.3V Supply

$V_{CC1} = V_{CC2} = 3.3V \pm 10\%$  (over recommended operating conditions unless otherwise noted)

| PARAMETER                                                                     | TEST CONDITIONS                                                 | MIN | TYP  | MAX | UNIT    |
|-------------------------------------------------------------------------------|-----------------------------------------------------------------|-----|------|-----|---------|
| $t_{PLH}$ , $t_{PHL}$ Propagation delay time                                  | See Figure 6-1                                                  | 6   | 10.8 | 16  | ns      |
| PWD Pulse width distortion <sup>(1)</sup> $ t_{PHL} - t_{PLH} $               |                                                                 |     | 0.7  | 4.2 | ns      |
| $t_{sk(o)}$ Channel-to-channel output skew time <sup>(2)</sup>                | Same-direction channels                                         |     |      | 2.2 | ns      |
| $t_{sk(pp)}$ Part-to-part skew time                                           |                                                                 |     |      | 4.5 | ns      |
| $t_r$ Output signal rise time                                                 | See Figure 6-1                                                  |     | 0.8  | 3   | ns      |
| $t_f$ Output signal fall time                                                 |                                                                 |     | 0.8  | 3   | ns      |
| $t_{PHZ}$ Disable propagation delay, high-to-high impedance output            | See Figure 6-2                                                  |     | 17   | 32  | ns      |
| $t_{PLZ}$ Disable propagation delay, low-to-high impedance output             |                                                                 |     | 17   | 32  | ns      |
| $t_{PZH}$ Enable propagation delay, high impedance-to-high output for ISO7840 |                                                                 |     | 17   | 32  | ns      |
| Enable propagation delay, high impedance-to-high output for ISO7840F          |                                                                 |     | 2    | 2.5 | $\mu s$ |
| $t_{PZL}$ Enable propagation delay, high impedance-to-low output for ISO7840  |                                                                 |     | 2    | 2.5 | $\mu s$ |
| Enable propagation delay, high impedance-to-low output for ISO7840F           |                                                                 |     | 17   | 32  | ns      |
| $t_{fs}$ Default output delay time from input power loss                      | Measured from the time $V_{CC}$ goes below 1.7V. See Figure 6-3 |     | 0.2  | 9   | $\mu s$ |
| $t_{ie}$ Time interval error                                                  | $2^{16} - 1$ PRBS data at 100Mbps                               |     | 0.91 |     | ns      |

(1) Also known as Pulse Skew.

(2)  $t_{sk(o)}$  is the skew between outputs of a single device with all driving inputs connected together and the outputs switching in the same direction while driving identical loads.

## 5.17 Switching Characteristics—2.5V Supply

$V_{CC1} = V_{CC2} = 2.5V \pm 10\%$  (over recommended operating conditions unless otherwise noted)

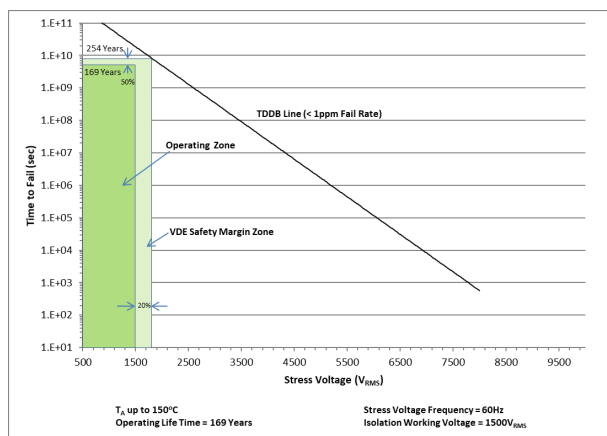
| PARAMETER                                                                     | TEST CONDITIONS                                                 | MIN | TYP  | MAX  | UNIT |
|-------------------------------------------------------------------------------|-----------------------------------------------------------------|-----|------|------|------|
| $t_{PLH}$ , $t_{PHL}$ Propagation delay time                                  | See Figure 6-1                                                  | 7.5 | 11.7 | 17.5 | ns   |
| PWD Pulse width distortion <sup>(1)</sup> $ t_{PHL} - t_{PLH} $               |                                                                 |     | 0.66 | 4.2  | ns   |
| $t_{sk(o)}$ Channel-to-channel output skew time <sup>(2)</sup>                | Same-direction Channels                                         |     |      | 2.2  | ns   |
| $t_{sk(pp)}$ Part-to-part skew time <sup>(3)</sup>                            |                                                                 |     |      | 4.5  | ns   |
| $t_r$ Output signal rise time                                                 | See Figure 6-1                                                  |     | 1    | 3.5  | ns   |
| $t_f$ Output signal fall time                                                 |                                                                 |     | 1.2  | 3.5  | ns   |
| $t_{PHZ}$ Disable propagation delay, high-to-high impedance output            | See Figure 6-2                                                  |     | 22   | 45   | ns   |
| $t_{PLZ}$ Disable propagation delay, low-to-high impedance output             |                                                                 |     | 22   | 45   | ns   |
| $t_{PZH}$ Enable propagation delay, high impedance-to-high output for ISO7840 |                                                                 |     | 18   | 45   | ns   |
| Enable propagation delay, high impedance-to-high output for ISO7840F          |                                                                 |     | 2    | 2.5  | μs   |
| $t_{PZL}$ Enable propagation delay, high impedance-to-low output for ISO7840  |                                                                 |     | 2    | 2.5  | μs   |
| Enable propagation delay, high impedance-to-low output for ISO7840F           |                                                                 |     | 18   | 45   | ns   |
| $t_{fs}$ Default output delay time from input power loss                      | Measured from the time $V_{CC}$ goes below 1.7V. See Figure 6-3 |     | 0.2  | 9    | μs   |
| $t_{ie}$ Time interval error                                                  | $2^{16} - 1$ PRBS data at 100Mbps                               |     | 0.91 |      | ns   |

(1) Also known as pulse skew.

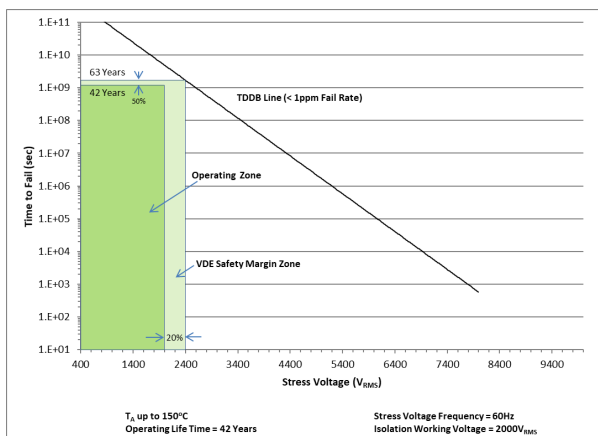
(2)  $t_{sk(o)}$  is the skew between outputs of a single device with all driving inputs connected together and the outputs switching in the same direction while driving identical loads.

(3)  $t_{sk(pp)}$  is the magnitude of the difference in propagation delay times between any terminals of different devices switching in the same direction while operating at identical supply voltages, temperature, input signals and loads.

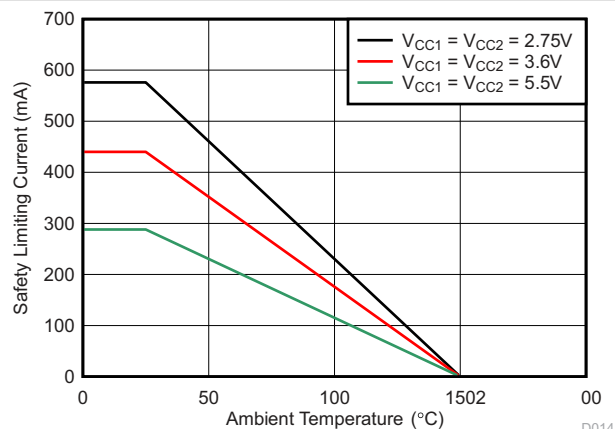
## 5.18 Insulation Characteristics Curves



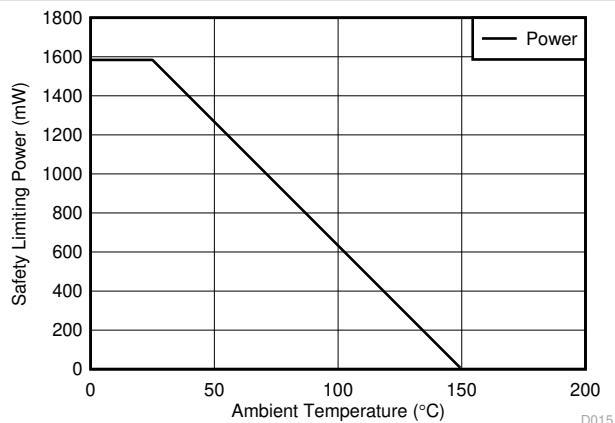
**Figure 5-1. Reinforced Isolation Capacitor Life Time Projection for Devices in DW Package**



**Figure 5-2. Reinforced Isolation Capacitor Life Time Projection for Devices in DWW Package**

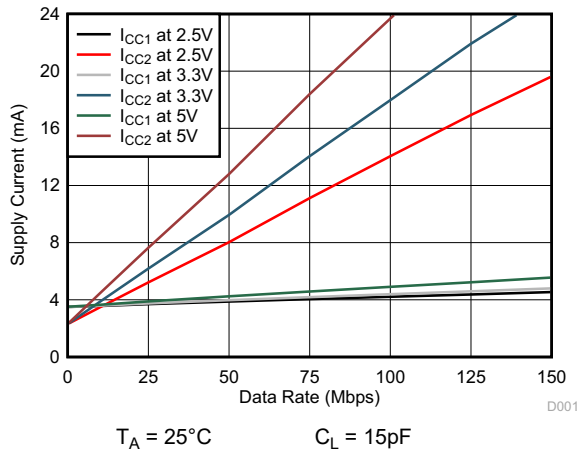


**Figure 5-3. Thermal Derating Curve for Limiting Current per VDE**

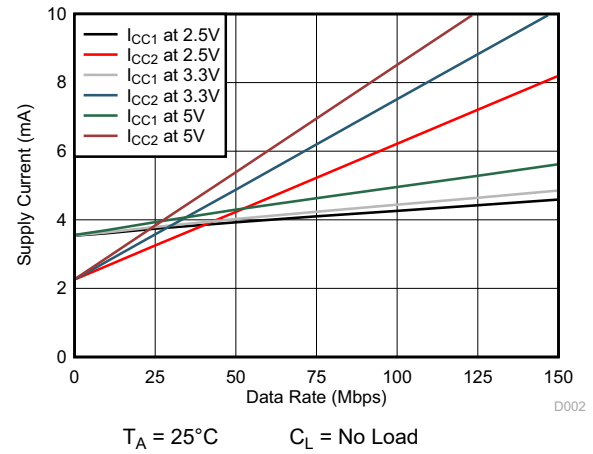


**Figure 5-4. Thermal Derating Curve for Limiting Power per VDE**

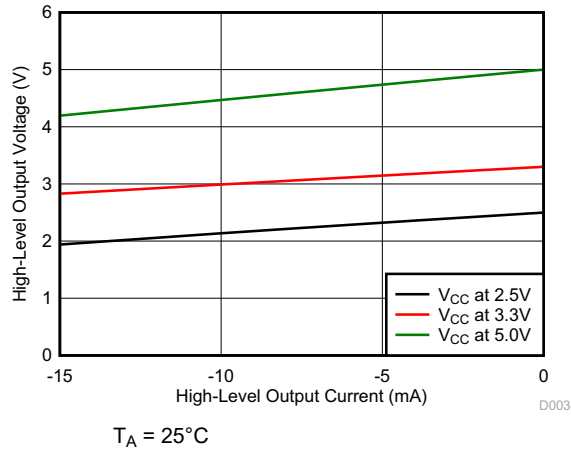
## 5.19 Typical Characteristics



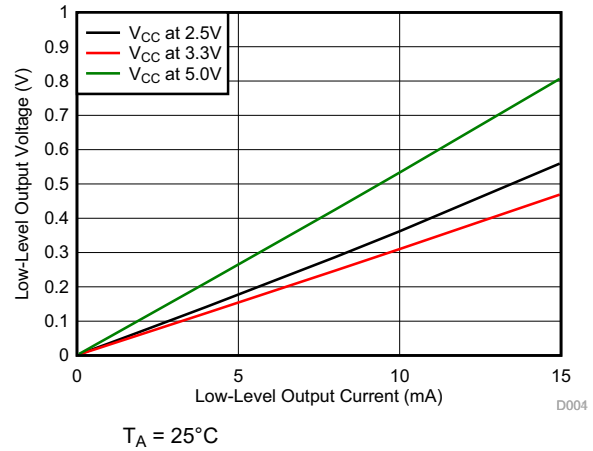
**Figure 5-5. Supply Current vs Data Rate (With 15pF Load)**



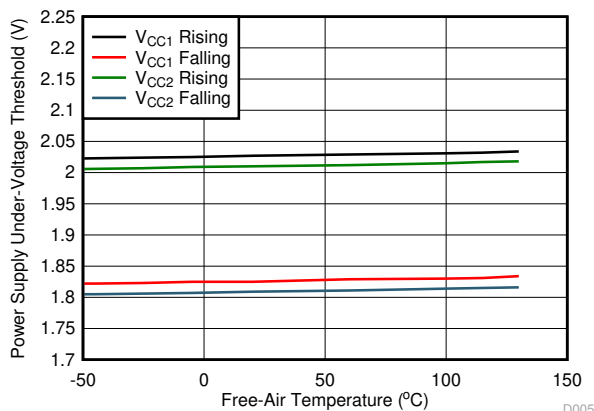
**Figure 5-6. Supply Current vs Data Rate (With No Load)**



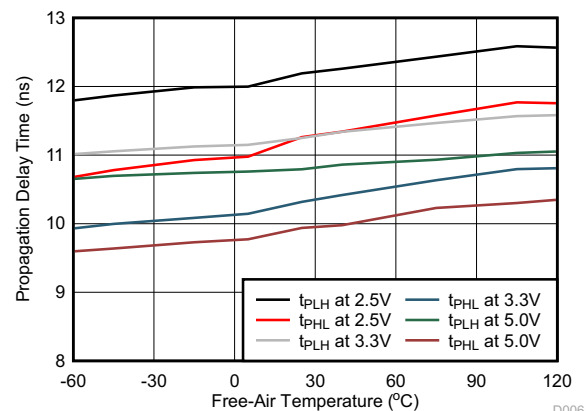
**Figure 5-7. High-Level Output Voltage vs High-level Output Current**



**Figure 5-8. Low-Level Output Voltage vs Low-Level Output Current**

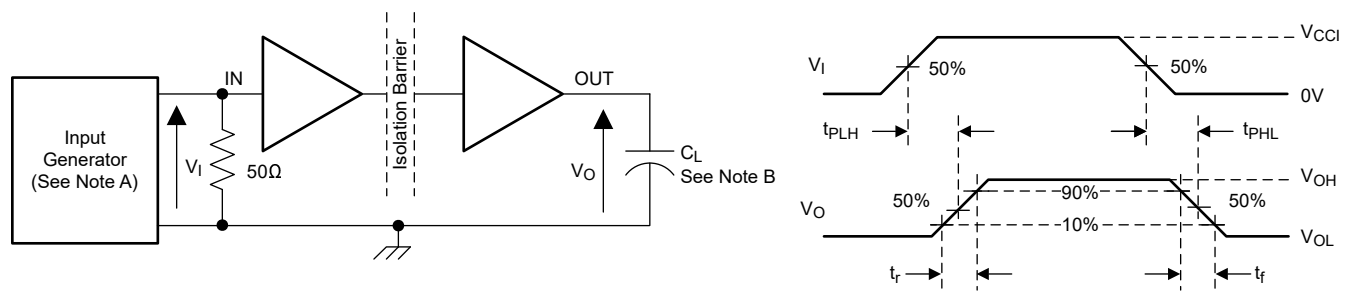


**Figure 5-9. Power Supply Undervoltage Threshold vs Free-Air Temperature**



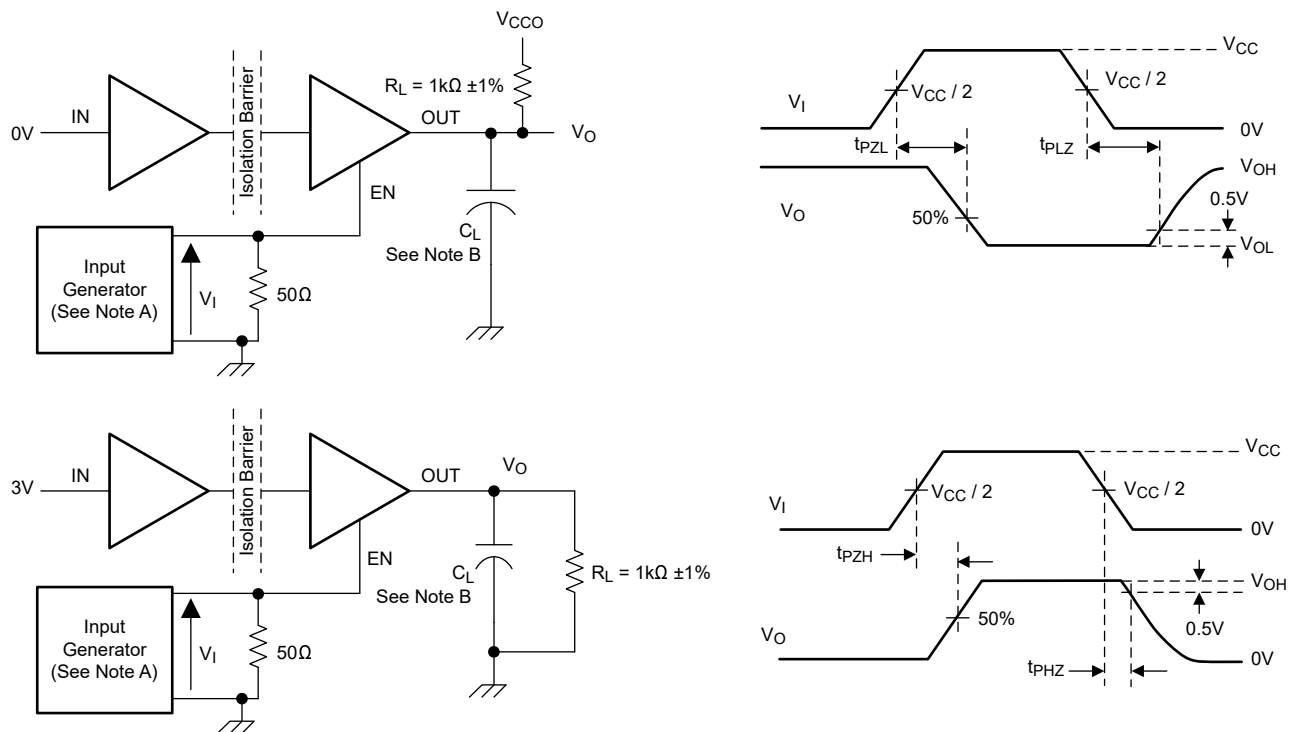
**Figure 5-10. Propagation Delay Time vs Free-Air Temperature**

## 6 Parameter Measurement Information



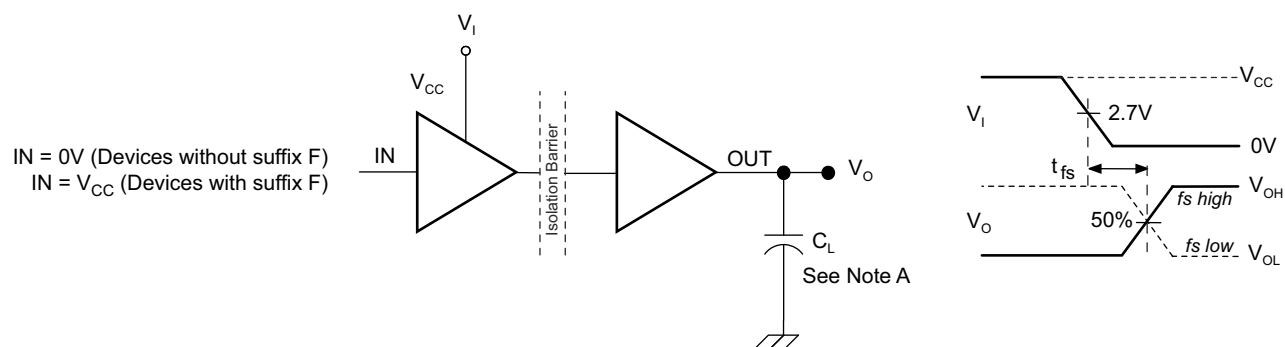
- A. The input pulse is supplied by a generator having the following characteristics:  $PRR \leq 50\text{kHz}$ , 50% duty cycle,  $t_r \leq 3\text{ns}$ ,  $t_f \leq 3\text{ns}$ ,  $Z_O = 50\Omega$ . At the input, a  $50\Omega$  resistor is required to terminate Input Generator signal. The  $50\Omega$  resistor is not needed in actual application.
- B.  $C_L = 15\text{pF}$  and includes instrumentation and fixture capacitance within  $\pm 20\%$ .

**Figure 6-1. Switching Characteristics Test Circuit and Voltage Waveforms**



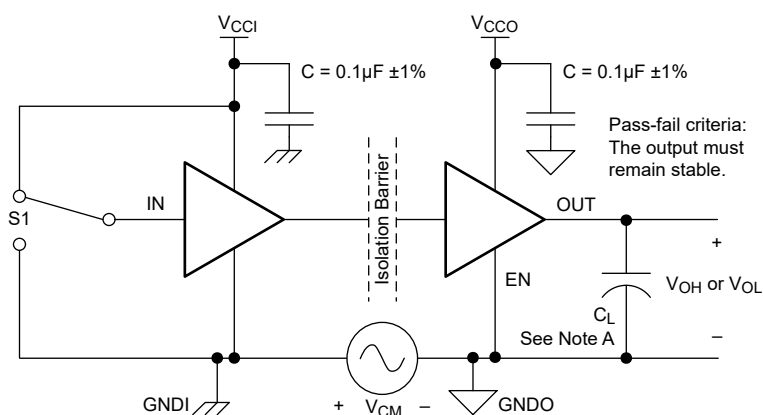
- A. The input pulse is supplied by a generator having the following characteristics:  $PRR \leq 10\text{kHz}$ , 50% duty cycle,  $t_r \leq 3\text{ns}$ ,  $t_f \leq 3\text{ns}$ ,  $Z_O = 5\Omega$ .
- B.  $C_L = 15\text{pF}$  and includes instrumentation and fixture capacitance within  $\pm 20\%$ .

**Figure 6-2. Enable/Disable Propagation Delay Time Test Circuit and Waveform**



A. C<sub>L</sub> = 15pF and includes instrumentation and fixture capacitance within ±20%.

**Figure 6-3. Default Output Delay Time Test Circuit and Voltage Waveforms**



A. C<sub>L</sub> = 15pF and includes instrumentation and fixture capacitance within ±20%.

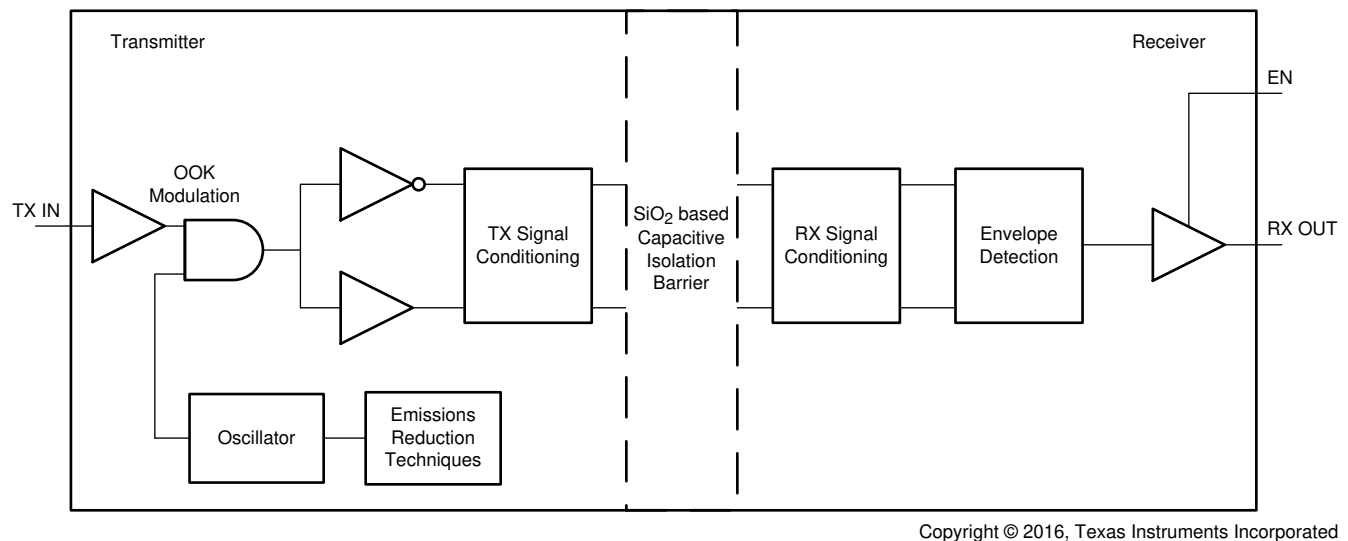
**Figure 6-4. Common-Mode Transient Immunity Test Circuit**

## 7 Detailed Description

### 7.1 Overview

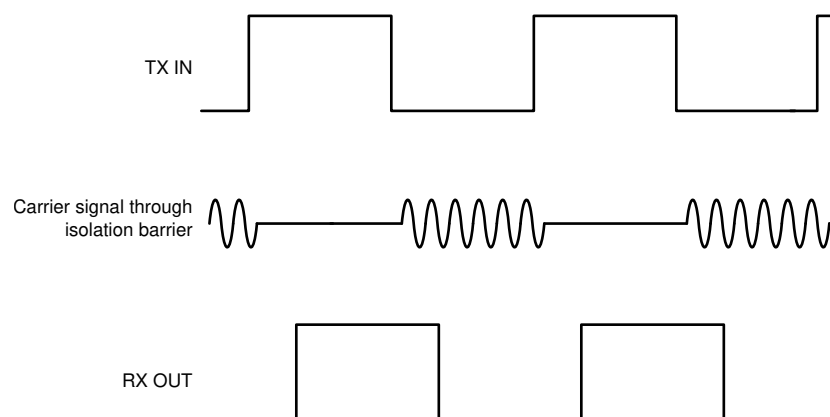
The ISO7840 device uses an ON-OFF keying (OOK) modulation scheme to transmit the digital data across a silicon-dioxide based isolation barrier. The transmitter sends a high-frequency carrier across the barrier to represent one digital state and sends no signal to represent the other digital state. The receiver demodulates the signal after advanced signal conditioning and produces the output through a buffer stage. If the EN pin is low then the output goes to high impedance. The ISO7840 device also incorporates advanced circuit techniques to maximize the CMTI performance and minimize the radiated emissions because of the high-frequency carrier and IO buffer switching. The conceptual block diagram of a digital capacitive isolator, [Figure 7-1](#), shows a functional block diagram of a typical channel.

### 7.2 Functional Block Diagram



**Figure 7-1. Conceptual Block Diagram of a Digital Capacitive Isolator**

[Figure 7-2](#) shows a conceptual detail of how the ON-OFF keying scheme works.



**Figure 7-2. On-Off Keying (OOK) Based Modulation Scheme**

## 7.3 Feature Description

Table 7-1 lists the device features.

**Table 7-1. Device Features**

| PART NUMBER | CHANNEL DIRECTION | RATED ISOLATION                                           | MAXIMUM DATA RATE | DEFAULT OUTPUT |
|-------------|-------------------|-----------------------------------------------------------|-------------------|----------------|
| ISO7840     | 4 Forward,        | 5700V <sub>RMS</sub> / 8000V <sub>PK</sub> <sup>(1)</sup> | 100Mbps           | High           |
|             | 0 Reverse         |                                                           |                   |                |
| ISO7840F    | 4 Forward,        | 5700V <sub>RMS</sub> / 8000V <sub>PK</sub> <sup>(1)</sup> | 100Mbps           | Low            |
|             | 0 Reverse         |                                                           |                   |                |

(1) See *Insulation Specifications* for detailed isolation ratings.

### 7.3.1 Electromagnetic Compatibility (EMC) Considerations

Many applications in harsh industrial environment are sensitive to disturbances such as electrostatic discharge (ESD), electrical fast transient (EFT), surge, and electromagnetic emissions. These electromagnetic disturbances are regulated by international standards such as IEC 61000-4-x and CISPR 22. Although system-level performance and reliability depends, to a large extent, on the application board design and layout, the ISO7840 device incorporates many chip-level design improvements for overall system robustness. Some of these improvements include

- Robust ESD protection cells for input and output signal pins and inter-chip bond pads.
- Low-resistance connectivity of ESD cells to supply and ground pins.
- Enhanced performance of high voltage isolation capacitor for better tolerance of ESD, EFT and surge events.
- Bigger on-chip decoupling capacitors to bypass undesirable high energy signals through a low impedance path.
- PMOS and NMOS devices isolated from each other by using guard rings to avoid triggering of parasitic SCRs.
- Reduced common mode currents across the isolation barrier by providing purely differential internal operation.

## 7.4 Device Functional Modes

Table 7-2 lists the ISO7840 functional modes.

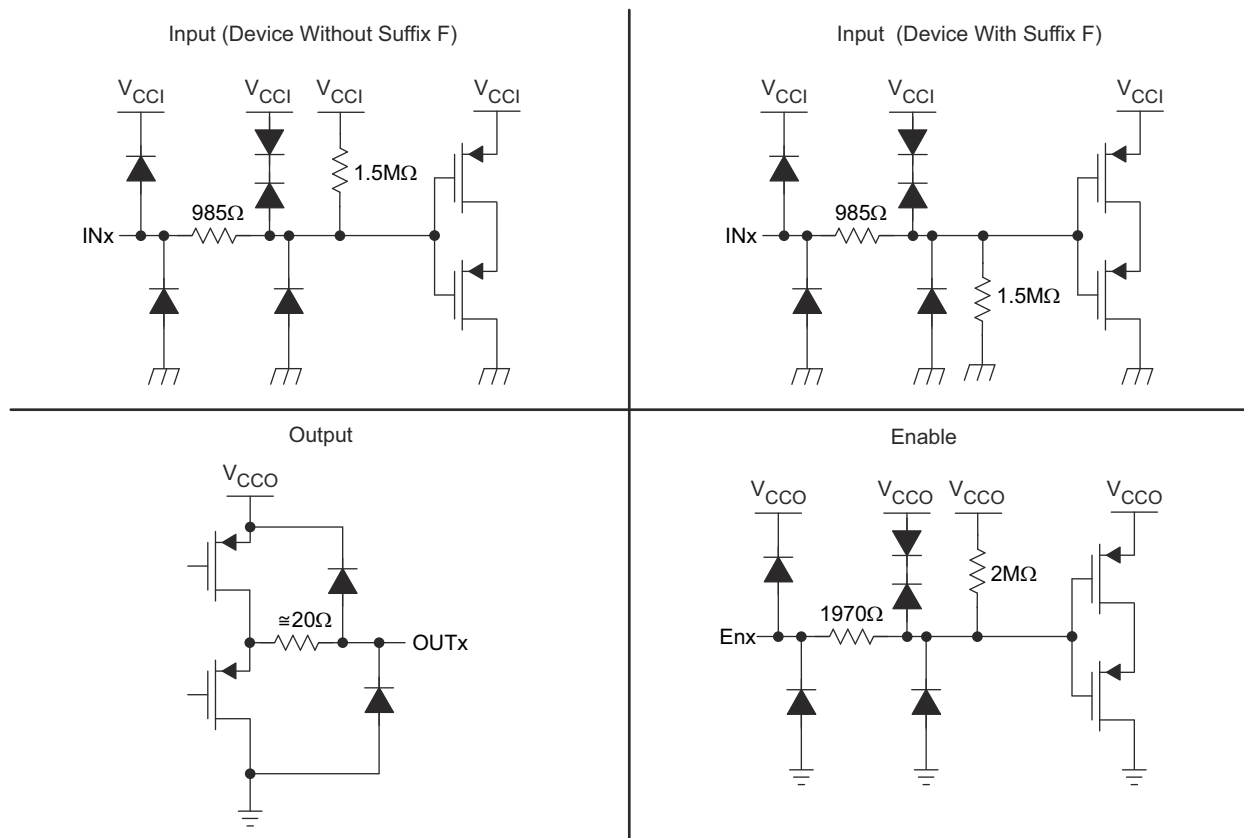
**Table 7-2. Function Table**

| V <sub>CCI</sub> | V <sub>CCO</sub> | INPUT<br>(INx) <sup>(2)</sup> | OUTPUT<br>ENABLE<br>(EN2) | OUTPUT<br>(OUTx) | COMMENTS                                                                                                                                                                                                                                                                                                                                                                                                                         |
|------------------|------------------|-------------------------------|---------------------------|------------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| PU               | PU               | H                             | H or open                 | H                | Normal Operation:<br>A channel output assumes the logic state of the input.                                                                                                                                                                                                                                                                                                                                                      |
|                  |                  | L                             | H or open                 | L                |                                                                                                                                                                                                                                                                                                                                                                                                                                  |
|                  |                  | Open                          | H or open                 | Default          | Default mode: When INx is open, the corresponding channel output goes to the default logic state. Default= High for ISO7840 and Low for ISO7840F.                                                                                                                                                                                                                                                                                |
| X                | PU               | X                             | L                         | Z                | A low value of Output Enable causes the outputs to be high-impedance                                                                                                                                                                                                                                                                                                                                                             |
| PD               | PU               | X                             | H or open                 | Default          | Default mode: When V <sub>CCI</sub> is unpowered, a channel output assumes the logic state based on the selected default option. Default= High for ISO7840 and Low for ISO7840F.<br>When V <sub>CCI</sub> transitions from unpowered to powered-up, a channel output assumes the logic state of the input.<br>When V <sub>CCI</sub> transitions from powered-up to unpowered, channel output assumes the selected default state. |
| X                | PD               | X                             | X                         | Undetermined     | When V <sub>CCO</sub> is unpowered, a channel output is undetermined <sup>(1)</sup> .<br>When V <sub>CCO</sub> transitions from unpowered to powered-up, a channel output assumes the logic state of the input                                                                                                                                                                                                                   |

(1) The outputs are undetermined when 1.7V < V<sub>CCI</sub>, V<sub>CCO</sub> < 2.25V.

(2) A strongly driven input signal can weakly power the floating V<sub>CC</sub> through an internal protection diode and cause undetermined output.

### 7.4.1 Device I/O Schematics



**Figure 7-3. Device I/O Schematics**

## 8 Application and Implementation

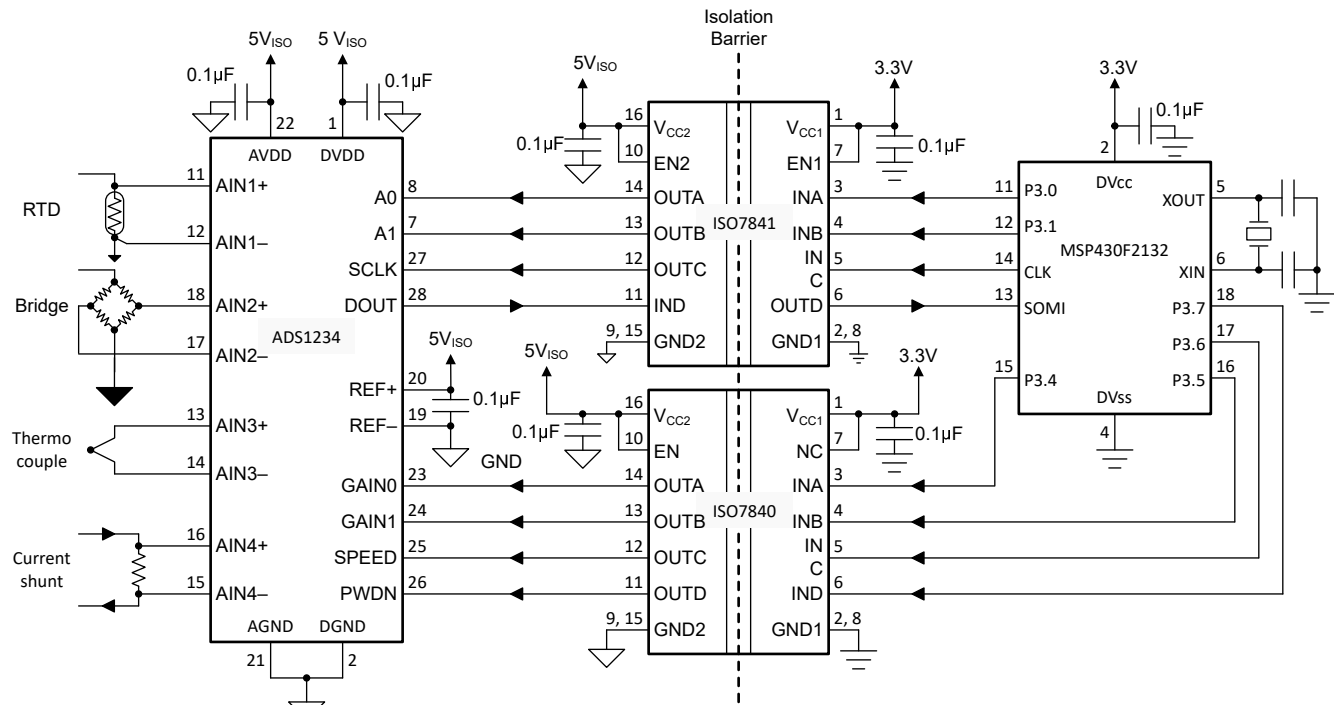
### Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

### 8.1 Application Information

The ISO7840 device is a high-performance, quad-channel digital isolator with a 5.7kV<sub>RMS</sub> isolation voltage. The device comes with enable pins on each side that can be used to put the respective outputs in high impedance for multi-controller driving applications and reduce power consumption. The ISO7840 device uses single-ended CMOS-logic switching technology. The supply voltage range is from 2.25V to 5.5V for both supplies, V<sub>CC1</sub> and V<sub>CC2</sub>. When designing with digital isolators, keep in mind that because of the single-ended design structure, digital isolators do not conform to any specific interface standard and are only intended for isolating single-ended CMOS or TTL digital signal lines. The isolator is typically placed between the data controller (that is,  $\mu$ C or UART), and a data converter or a line transceiver, regardless of the interface type or standard.

## 8.2 Typical Application



**Figure 8-1. Isolated Data Acquisition System for Process Control**

### 8.2.1 Design Requirements

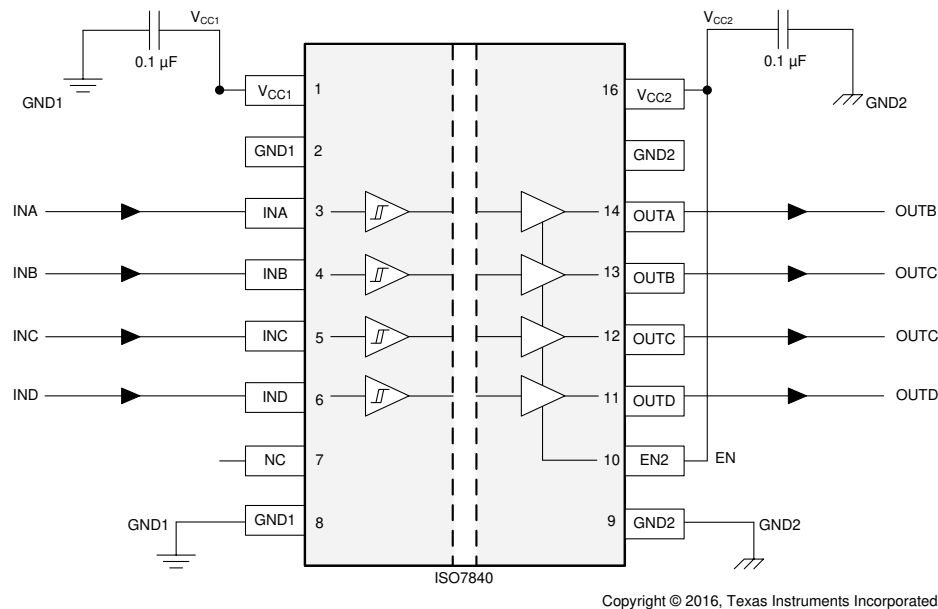
For this design example, use the parameters shown in [Table 8-1](#).

**Table 8-1. Design Parameters**

| PARAMETER                                              | VALUE         |
|--------------------------------------------------------|---------------|
| Supply voltage                                         | 2.25V to 5.5V |
| Decoupling capacitor between V <sub>CC1</sub> and GND1 | 0.1µF         |
| Decoupling capacitor from V <sub>CC2</sub> and GND2    | 0.1µF         |

### 8.2.2 Detailed Design Procedure

Unlike optocouplers, which require external components to improve performance, provide bias, or limit current, the ISO7840 device only requires two external bypass capacitors to operate.

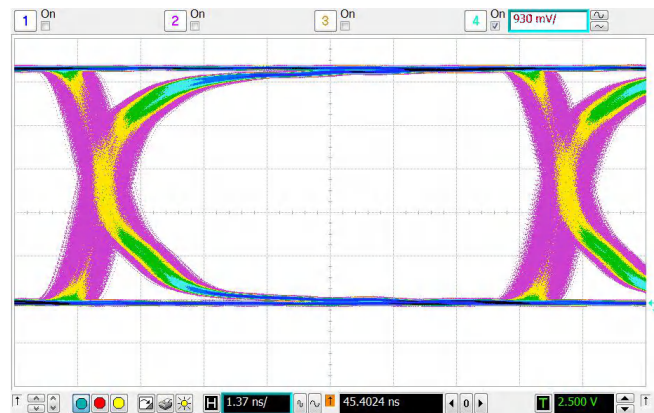


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**Figure 8-2. Typical ISO7840 Circuit Hook-Up**

### 8.2.3 Application Curve

The typical eye diagram of the ISO7840 device indicates low jitter and wide open eye at the maximum data rate of 100Mbps.

**Figure 8-3. Eye Diagram at 100Mbps PRBS, 5V and 25°C**

### 8.3 Power Supply Recommendations

To help provide reliable operation at data rates and supply voltages, a 0.1μF bypass capacitor is recommended at input and output supply pins ( $V_{CC1}$  and  $V_{CC2}$ ). The capacitors must be placed as close to the supply pins as possible. If only a single primary-side power supply is available in an application, isolated power can be generated for the secondary-side with the help of a transformer driver such as Texas Instruments [SN6501](#). For such applications, detailed power supply design and transformer selection recommendations are available in [SN6501 Transformer Driver for Isolated Power Supplies](#).

## 8.4 Layout

### 8.4.1 Layout Guidelines

A minimum of four layers is required to accomplish a low EMI PCB design (see [Figure 8-4](#)). Layer stacking must be in the following order (top-to-bottom): high-speed signal layer, ground plane, power plane and low-frequency signal layer.

- Routing the high-speed traces on the top layer avoids the use of vias (and the introduction of the inductances) and allows for clean interconnects between the isolator and the transmitter and receiver circuits of the data link.
- Placing a solid ground plane next to the high-speed signal layer establishes controlled impedance for transmission line interconnects and provides an excellent low-inductance path for the return current flow.
- Placing the power plane next to the ground plane creates additional high-frequency bypass capacitance of approximately 100pF/inch<sup>2</sup>.
- Routing the slower speed control signals on the bottom layer allows for greater flexibility as these signal links typically have margin to tolerate discontinuities such as vias.

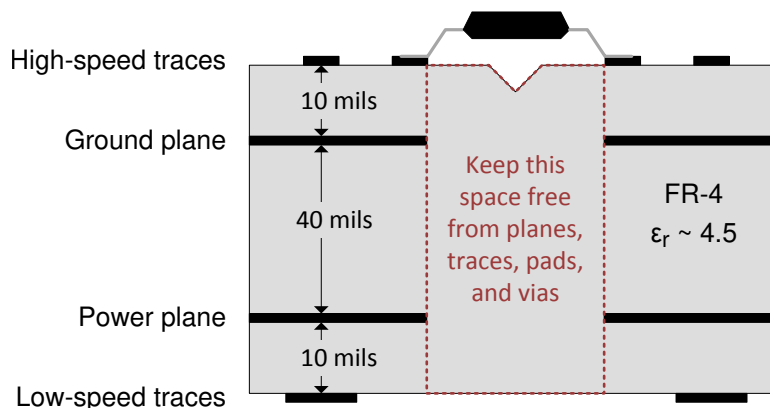
If an additional supply voltage plane or signal layer is needed, add a second power or ground plane system to the stack to keep the planes symmetrical. This makes the stack mechanically stable and prevents warping. Also the power and ground plane of each power system can be placed closer together, thus increasing the high-frequency bypass capacitance significantly.

For detailed layout recommendations, refer to [Digital Isolator Design Guide](#).

#### 8.4.1.1 PCB Material

For digital circuit boards operating at less than 150Mbps, (or rise and fall times greater than 1ns), and trace lengths of up to 10 inches, use standard FR-4 UL94V-0 printed circuit board. This PCB is preferred over cheaper alternatives because of lower dielectric losses at high frequencies, less moisture absorption, greater strength and stiffness, and the self-extinguishing flammability-characteristics.

### 8.4.2 Layout Example



**Figure 8-4. Layout Example Schematic**

## 9 Device and Documentation Support

### 9.1 Documentation Support

#### 9.1.1 Related Documentation

For related documentation, see the following:

- Texas Instruments, [DS123x 2- and 4-Channel, 24-Bit, Delta-Sigma ADCs for Bridge Sensors](#), data sheet
- Texas Instruments, [Digital Isolator Design Guide](#), application note
- Texas Instruments, [Isolation Glossary](#), application note
- Texas Instruments, [MSP430G2x32, MSP430G2x02 Mixed Signal Microcontrollers](#), data sheet
- Texas Instruments, [Transformer Driver for Isolated Power Supplies](#), data sheet

### 9.2 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

**Table 9-1. Related Links**

| PARTS    | PRODUCT FOLDER             | ORDER NOW                  | TECHNICAL DOCUMENTS        | TOOLS & SOFTWARE           | SUPPORT & COMMUNITY        |
|----------|----------------------------|----------------------------|----------------------------|----------------------------|----------------------------|
| ISO7840  | <a href="#">Click here</a> | <a href="#">Click here</a> | <a href="#">Click here</a> | <a href="#">Click here</a> | <a href="#">Click here</a> |
| ISO7840F | <a href="#">Click here</a> | <a href="#">Click here</a> | <a href="#">Click here</a> | <a href="#">Click here</a> | <a href="#">Click here</a> |

### 9.3 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

### 9.4 Support Resources

**TI E2E™ support forums** are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

### 9.5 Trademarks

TI E2E™ is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

### 9.6 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

### 9.7 Glossary

**TI Glossary** This glossary lists and explains terms, acronyms, and definitions.

## 10 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

| Changes from Revision B (April 2016) to Revision C (July 2025)                          | Page |
|-----------------------------------------------------------------------------------------|------|
| • Added 15mm typical specification for CLR/CPG in <i>Insulation Specification</i> ..... | 6    |

- Added the *Receiving Notification of Documentation Updates* section.....24

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#### Changes from Revision A (March 2016) to Revision B (April 2016) Page

|                                                                                                                                                          |    |
|----------------------------------------------------------------------------------------------------------------------------------------------------------|----|
| • Added <i>Features</i> 2.25V to 5.5V Level Translation.....                                                                                             | 1  |
| • Changed the number of years for the isolation barrier life in the <i>Features</i> section .....                                                        | 1  |
| • VDE certification is now complete .....                                                                                                                | 1  |
| • Changed the input-to-output test voltage parameter to apparent charge in the <i>Insulation Specifications</i> .....                                    | 6  |
| • Changed $V_{CCO}$ to $V_{CCI}$ for the minimum value of the input threshold voltage hysteresis parameter in all electrical characteristics tables..... | 8  |
| • Added $V_{CM}$ to the test condition of the common-mode transient immunity parameter in all electrical characteristics tables.....                     | 8  |
| • Added the lifetime projection graphs for DW and DWW packages to the <i>Safety Limiting Values</i> section .....                                        | 14 |

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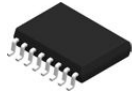
#### Changes from Revision \* (July 2015) to Revision A (February 2016) Page

|                                                                                                                                                                                        |    |
|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|----|
| • Changed <i>Features</i> From: Industry leading CMTI To: Industry leading CMTI (MIN) .....                                                                                            | 1  |
| • Changed the Safety and Regulatory Approvals list of <i>Features</i> .....                                                                                                            | 1  |
| • Added <i>Features</i> "TUV Certification per EN 61010-1 and EN 60950-1".....                                                                                                         | 1  |
| • Changed text in the first paragraph of the <i>Description</i> From: "certifications according to VDE, CSA, and CQC". To: "certifications according to VDE, CSA, CQC, and TUV." ..... | 1  |
| • Added the DWW package to the <a href="#">Section 5.4</a> .....                                                                                                                       | 5  |
| • Changed <i>Package Insulation and Safety-Related Specifications</i> , added the 16-DWW Package information...                                                                        | 6  |
| • Added the DWW package information, added "Climatic category", and deleted Note 1 in <i>Insulation Characteristics</i> .....                                                          | 6  |
| • Added Note 1 to <i>Insulation Characteristics</i> .....                                                                                                                              | 6  |
| • Changed <i>IEC 60664-1 Ratings Table</i> .....                                                                                                                                       | 6  |
| • Added the TUV and DWW package information to the <i>Regulatory Information</i> section and Regulatory Information. Deleted Note 1 in Regulatory Information.....                     | 7  |
| • Changed the Supply Current section of <i>Supply Characteristics—5V Supply</i> .....                                                                                                  | 8  |
| • Changed the Supply Current section of <i>Supply Current Characteristics—3.3V Supply</i> .....                                                                                        | 9  |
| • Changed the Supply Current section of <i>Supply Current Characteristics—2.5V Supply</i> .....                                                                                        | 10 |
| • Changed Device I/O Schematics .....                                                                                                                                                  | 20 |

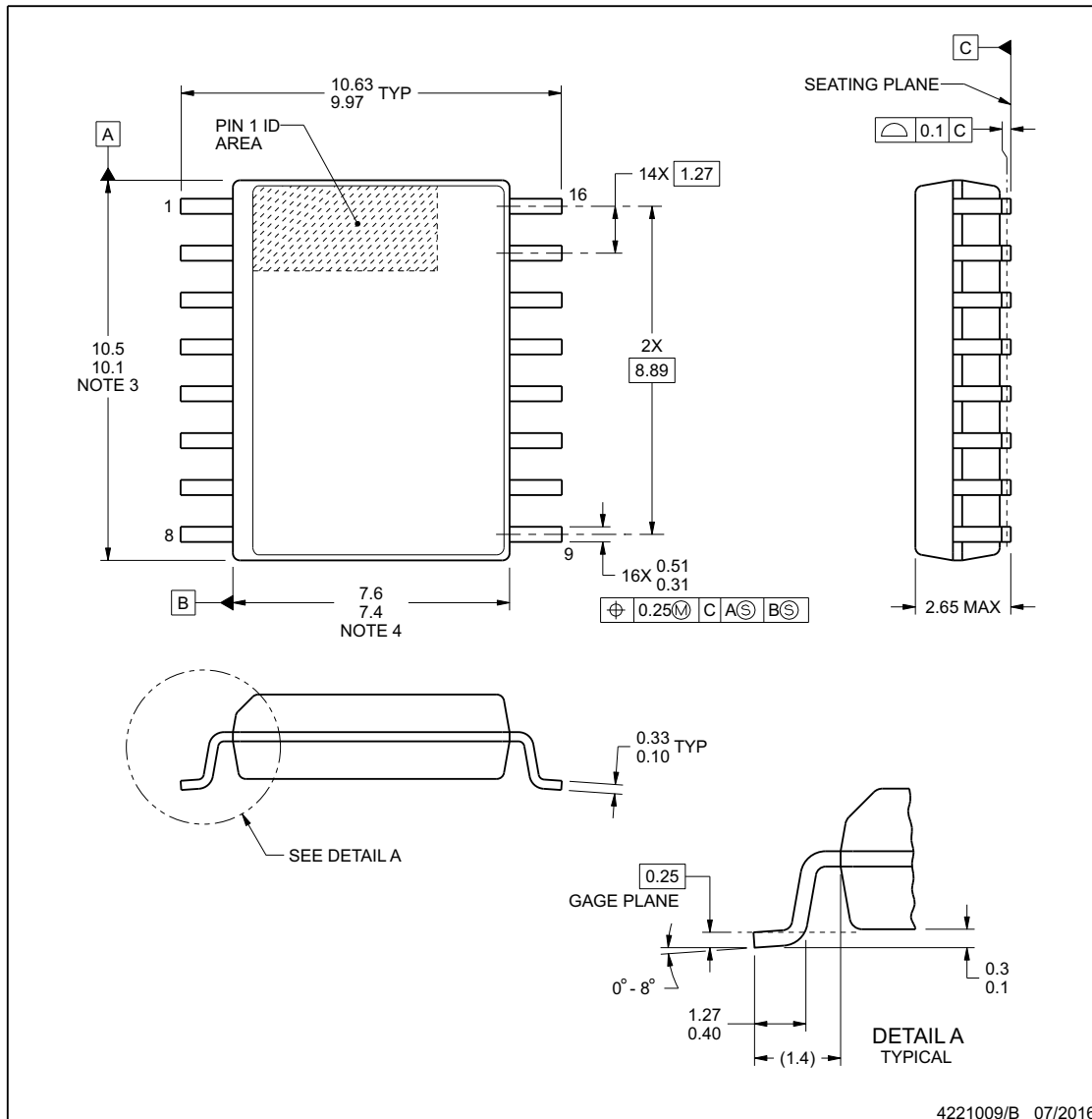
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## 11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical packaging and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

**DW0016B****PACKAGE OUTLINE****SOIC - 2.65 mm max height**

SOIC



4221009/B 07/2016

**NOTES:**

1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm, per side.
5. Reference JEDEC registration MS-013.

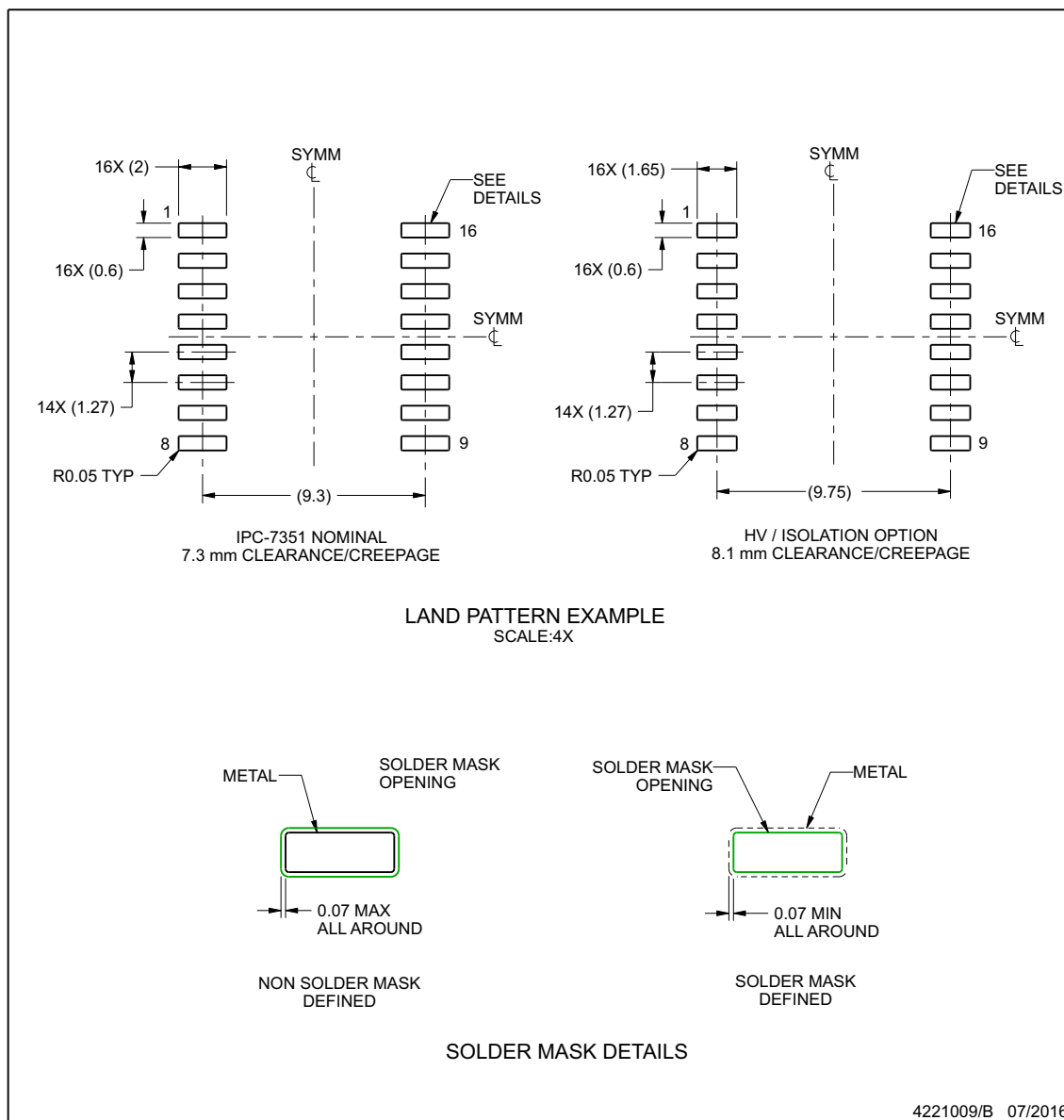
www.ti.com

## EXAMPLE BOARD LAYOUT

**DW0016B**

**SOIC - 2.65 mm max height**

SOIC



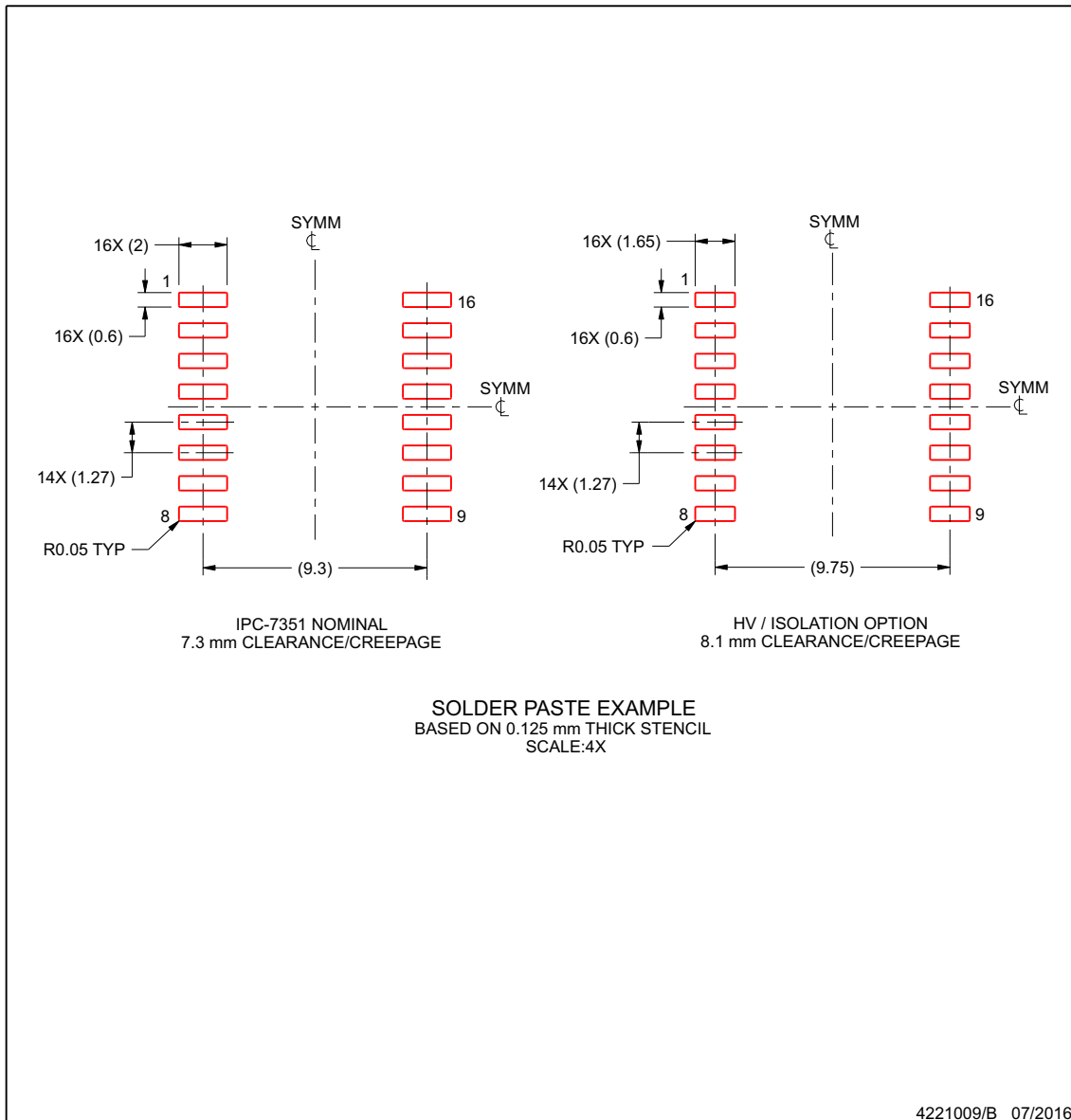
NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

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**EXAMPLE STENCIL DESIGN****DW0016B****SOIC - 2.65 mm max height**

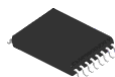
SOIC



NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

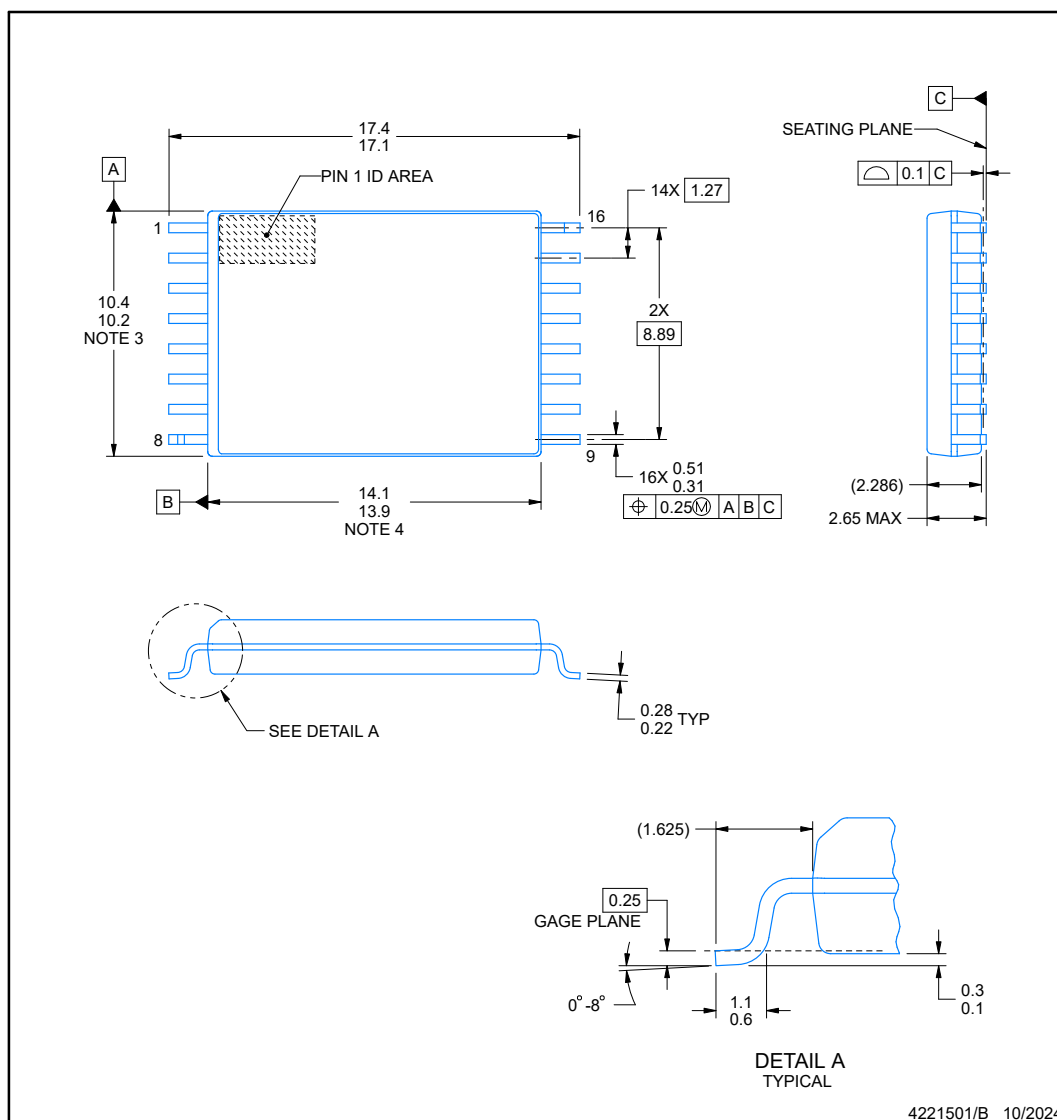
www.ti.com



## DWW0016A

## PACKAGE OUTLINE SOIC - 2.65 mm max height

PLASTIC SMALL OUTLINE

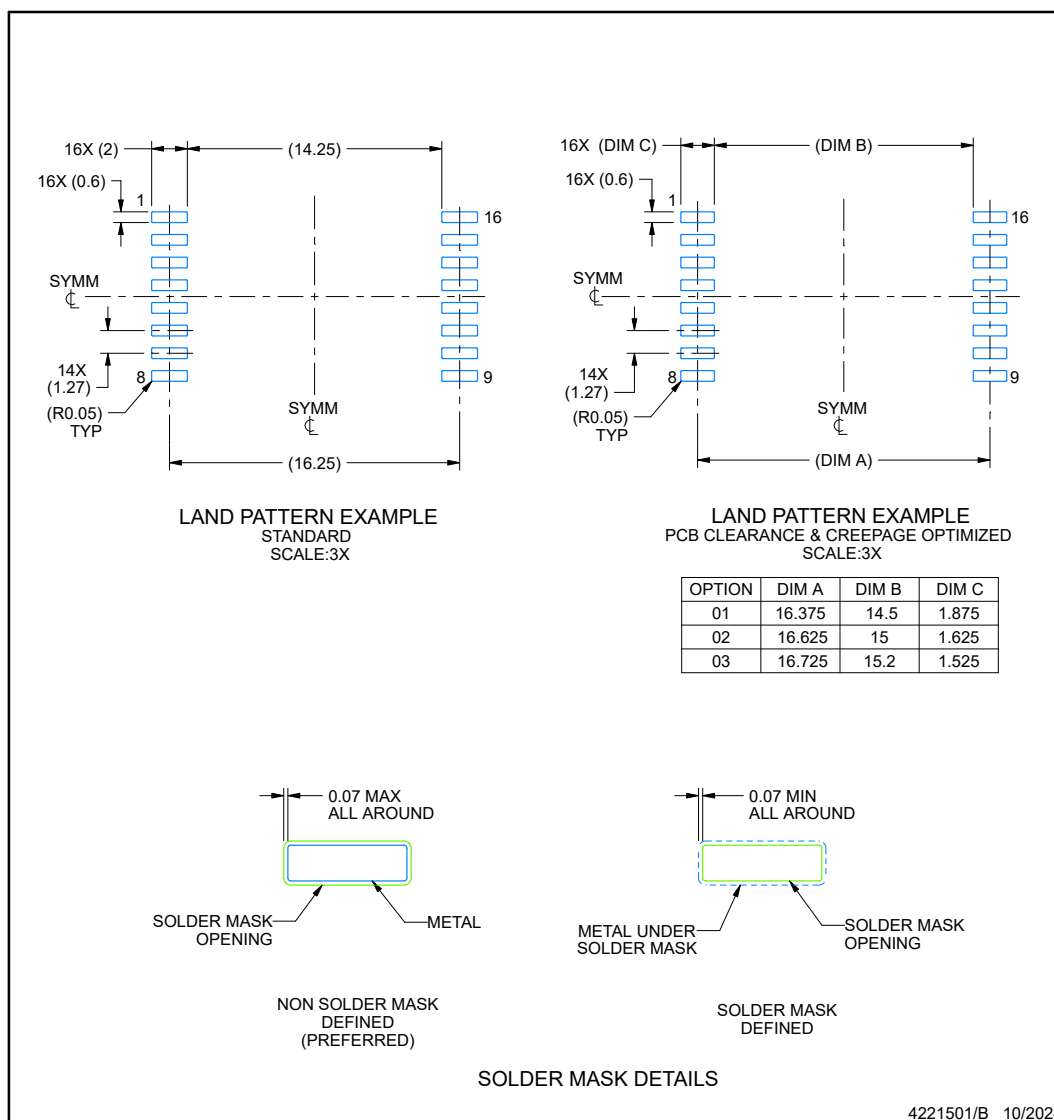


### NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash.

**EXAMPLE BOARD LAYOUT****DWW0016A****SOIC - 2.65 mm max height**

PLASTIC SMALL OUTLINE



NOTES: (continued)

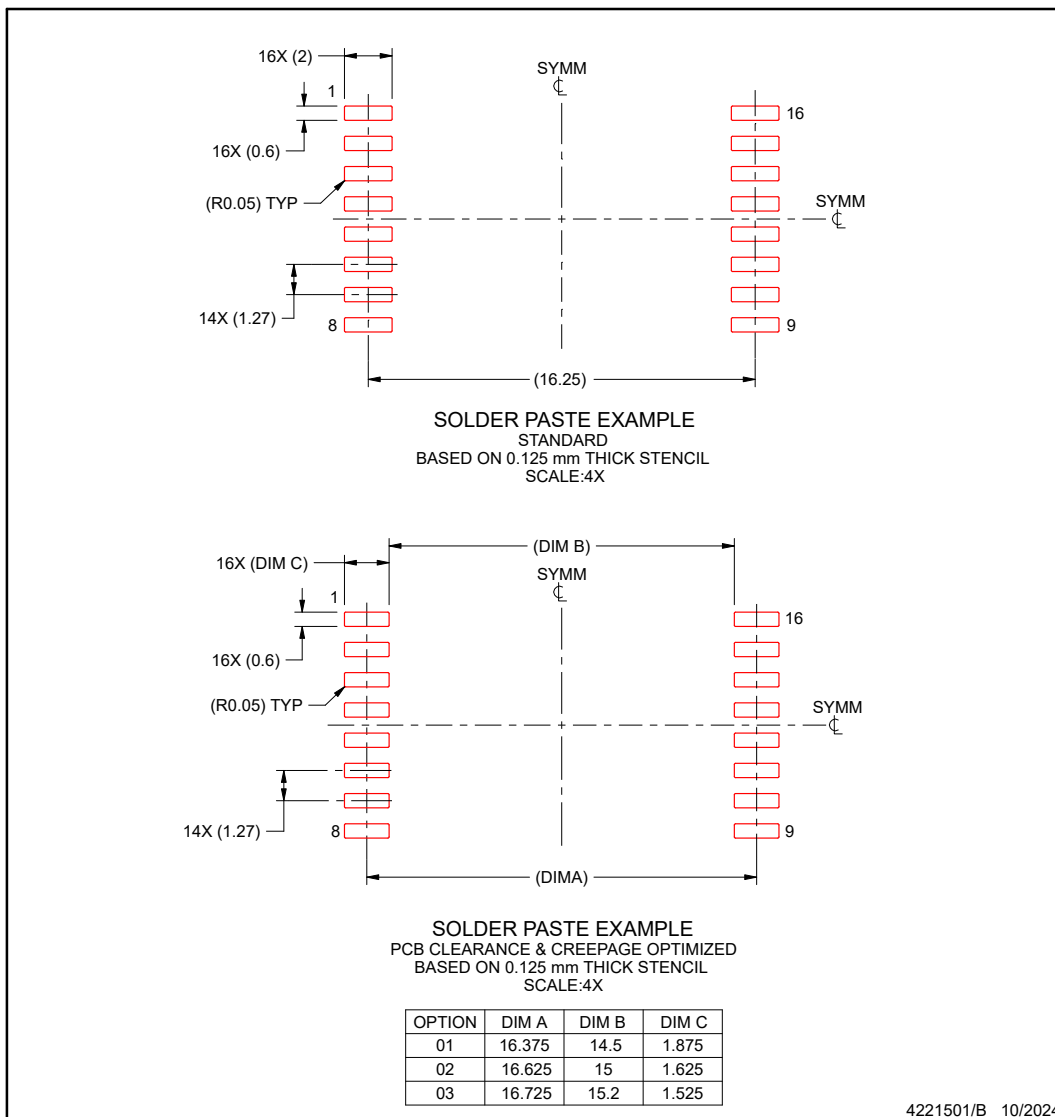
5. Publication IPC-7351 may have alternate designs.
6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

## EXAMPLE STENCIL DESIGN

**DWW0016A**

**SOIC - 2.65 mm max height**

PLASTIC SMALL OUTLINE



NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
8. Board assembly site may have different recommendations for stencil design.

## PACKAGING INFORMATION

| Orderable part number        | Status<br>(1) | Material type<br>(2) | Package   Pins  | Package qty   Carrier | RoHS<br>(3) | Lead finish/<br>Ball material<br>(4) | MSL rating/<br>Peak reflow<br>(5) | Op temp (°C) | Part marking<br>(6) |
|------------------------------|---------------|----------------------|-----------------|-----------------------|-------------|--------------------------------------|-----------------------------------|--------------|---------------------|
| <a href="#">ISO7840DW</a>    | Active        | Production           | SOIC (DW)   16  | 40   TUBE             | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -55 to 125   | ISO7840             |
| ISO7840DW.A                  | Active        | Production           | SOIC (DW)   16  | 40   TUBE             | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -55 to 125   | ISO7840             |
| <a href="#">ISO7840DWR</a>   | Active        | Production           | SOIC (DW)   16  | 2000   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -55 to 125   | ISO7840             |
| ISO7840DWR.A                 | Active        | Production           | SOIC (DW)   16  | 2000   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -55 to 125   | ISO7840             |
| <a href="#">ISO7840DWW</a>   | Active        | Production           | SOIC (DWW)   16 | 45   TUBE             | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -55 to 125   | ISO7840             |
| ISO7840DWW.A                 | Active        | Production           | SOIC (DWW)   16 | 45   TUBE             | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -55 to 125   | ISO7840             |
| <a href="#">ISO7840DWWR</a>  | Active        | Production           | SOIC (DWW)   16 | 1000   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -55 to 125   | ISO7840             |
| ISO7840DWWR.A                | Active        | Production           | SOIC (DWW)   16 | 1000   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -55 to 125   | ISO7840             |
| <a href="#">ISO7840FDW</a>   | Active        | Production           | SOIC (DW)   16  | 40   TUBE             | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -55 to 125   | ISO7840F            |
| ISO7840FDW.A                 | Active        | Production           | SOIC (DW)   16  | 40   TUBE             | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -55 to 125   | ISO7840F            |
| <a href="#">ISO7840FDWR</a>  | Active        | Production           | SOIC (DW)   16  | 2000   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -55 to 125   | ISO7840F            |
| ISO7840FDWR.A                | Active        | Production           | SOIC (DW)   16  | 2000   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -55 to 125   | ISO7840F            |
| ISO7840FDWRG4                | Active        | Production           | SOIC (DW)   16  | 2000   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -55 to 125   | ISO7840F            |
| ISO7840FDWRG4.A              | Active        | Production           | SOIC (DW)   16  | 2000   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -55 to 125   | ISO7840F            |
| <a href="#">ISO7840FDWW</a>  | Active        | Production           | SOIC (DWW)   16 | 45   TUBE             | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -55 to 125   | ISO7840F            |
| ISO7840FDWW.A                | Active        | Production           | SOIC (DWW)   16 | 45   TUBE             | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -55 to 125   | ISO7840F            |
| <a href="#">ISO7840FDWWR</a> | Active        | Production           | SOIC (DWW)   16 | 1000   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -55 to 125   | ISO7840F            |
| ISO7840FDWWR.A               | Active        | Production           | SOIC (DWW)   16 | 1000   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -55 to 125   | ISO7840F            |

<sup>(1)</sup> **Status:** For more details on status, see our [product life cycle](#).

<sup>(2)</sup> **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

<sup>(4)</sup> **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

**Important Information and Disclaimer:** The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

## TAPE AND REEL INFORMATION



\*All dimensions are nominal

| Device        | Package Type | Package Drawing | Pins | SPQ  | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|---------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| ISO7840DWR    | SOIC         | DW              | 16   | 2000 | 330.0              | 16.4               | 10.75   | 10.7    | 2.7     | 12.0    | 16.0   | Q1            |
| ISO7840DWWR   | SOIC         | DWW             | 16   | 1000 | 330.0              | 24.4               | 18.0    | 10.0    | 3.0     | 20.0    | 24.0   | Q1            |
| ISO7840FDWR   | SOIC         | DW              | 16   | 2000 | 330.0              | 16.4               | 10.75   | 10.7    | 2.7     | 12.0    | 16.0   | Q1            |
| ISO7840FDWRG4 | SOIC         | DW              | 16   | 2000 | 330.0              | 16.4               | 10.75   | 10.7    | 2.7     | 12.0    | 16.0   | Q1            |
| ISO7840FDWWR  | SOIC         | DWW             | 16   | 1000 | 330.0              | 24.4               | 18.0    | 10.0    | 3.0     | 20.0    | 24.0   | Q1            |

## TAPE AND REEL BOX DIMENSIONS



\*All dimensions are nominal

| Device        | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|---------------|--------------|-----------------|------|------|-------------|------------|-------------|
| ISO7840DWR    | SOIC         | DW              | 16   | 2000 | 350.0       | 350.0      | 43.0        |
| ISO7840DWWR   | SOIC         | DWW             | 16   | 1000 | 350.0       | 350.0      | 43.0        |
| ISO7840FDWR   | SOIC         | DW              | 16   | 2000 | 350.0       | 350.0      | 43.0        |
| ISO7840FDWRG4 | SOIC         | DW              | 16   | 2000 | 350.0       | 350.0      | 43.0        |
| ISO7840FDWWR  | SOIC         | DWW             | 16   | 1000 | 350.0       | 350.0      | 43.0        |

## TUBE



\*All dimensions are nominal

| Device        | Package Name | Package Type | Pins | SPQ | L (mm) | W (mm) | T (μm) | B (mm) |
|---------------|--------------|--------------|------|-----|--------|--------|--------|--------|
| ISO7840DW     | DW           | SOIC         | 16   | 40  | 506.98 | 12.7   | 4826   | 6.6    |
| ISO7840DW.A   | DW           | SOIC         | 16   | 40  | 506.98 | 12.7   | 4826   | 6.6    |
| ISO7840DWW    | DWW          | SOIC         | 16   | 45  | 507    | 20     | 5000   | 9      |
| ISO7840DWW.A  | DWW          | SOIC         | 16   | 45  | 507    | 20     | 5000   | 9      |
| ISO7840FDW    | DW           | SOIC         | 16   | 40  | 506.98 | 12.7   | 4826   | 6.6    |
| ISO7840FDW.A  | DW           | SOIC         | 16   | 40  | 506.98 | 12.7   | 4826   | 6.6    |
| ISO7840FDWW   | DWW          | SOIC         | 16   | 45  | 507    | 20     | 5000   | 9      |
| ISO7840FDWW.A | DWW          | SOIC         | 16   | 45  | 507    | 20     | 5000   | 9      |

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